

# EMC – Workshop

## Rauischholzhausen

### November 24-25, 2014

## AGENDA

Subjects to be discussed:

- Crystals
- Photosensors (APD screening, Test procedure, VPTT?)
- Cooling and isolation
- Prototypes (PROTO120, Maxlab results, )
- Stimulated Recovery
- Electronics chain: PA, ASIC, Driver, SADC, Cables, ...)
- Installation @ PANDA site (Rackspace, ...)
- Status on Forward/Backward Endcaps
- Status on Barrel Mechanics
- Timelines

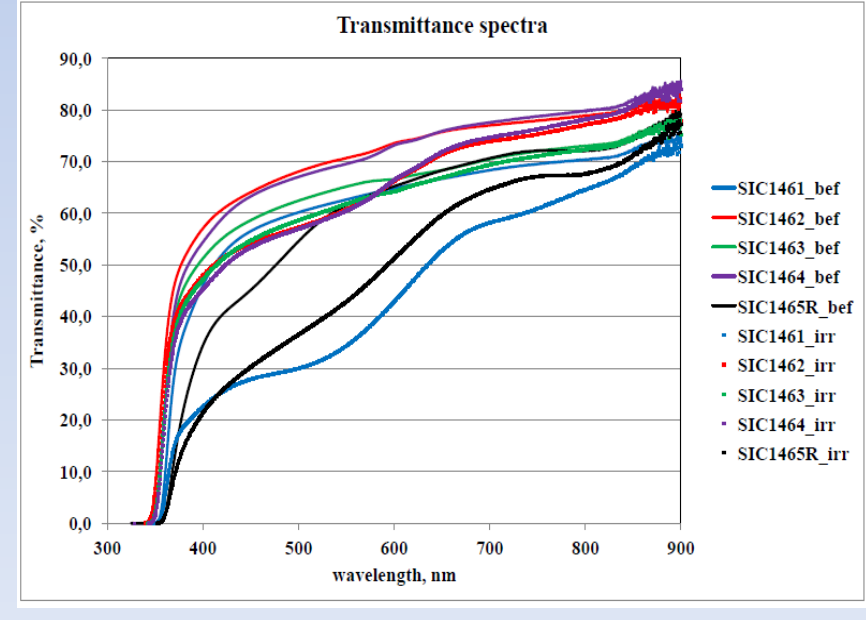
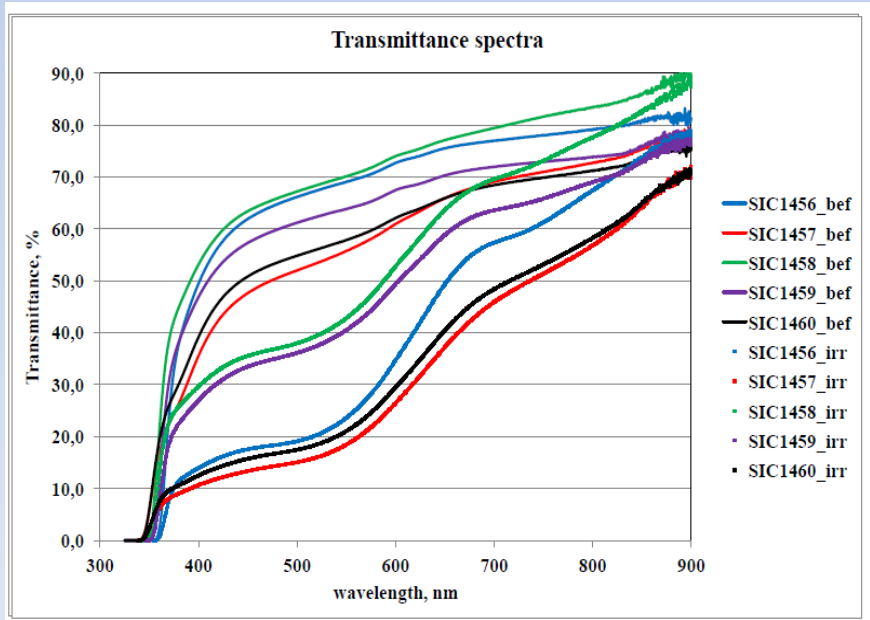
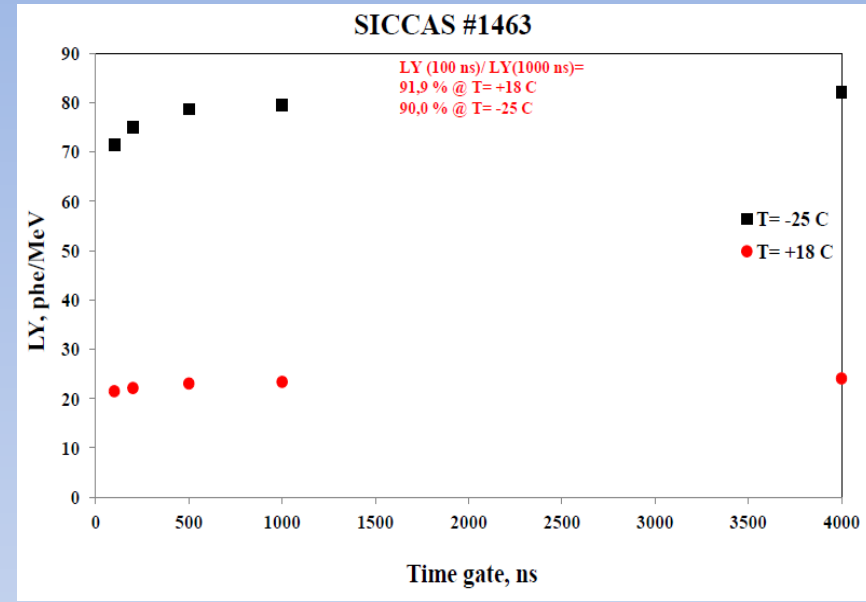
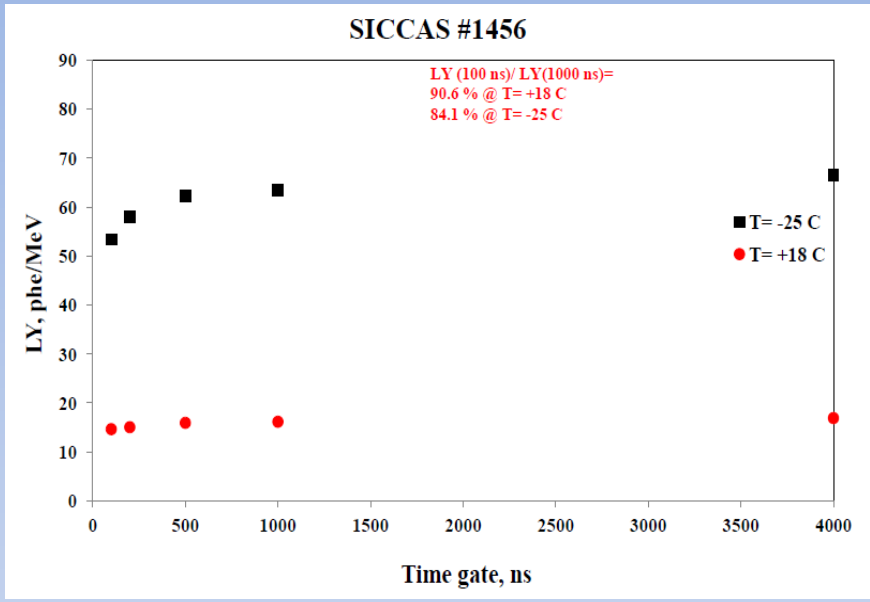
# contributions:

- Claudius Schnier: **Cabeling, Voltage distribution etc. for FW Endcap**
- Tobias Triffterer: **DCS fürs EMC: alarm system etc.**
  
- Christoph Rosenbaum: **The status on PROTO 120**
- Stefan Diehl: **Completion of PROTO 120**
- Till Kuske: **Status on recovery**
  
- Rainer Novotny: **News on crystals from SICCAS and CRYTUR**

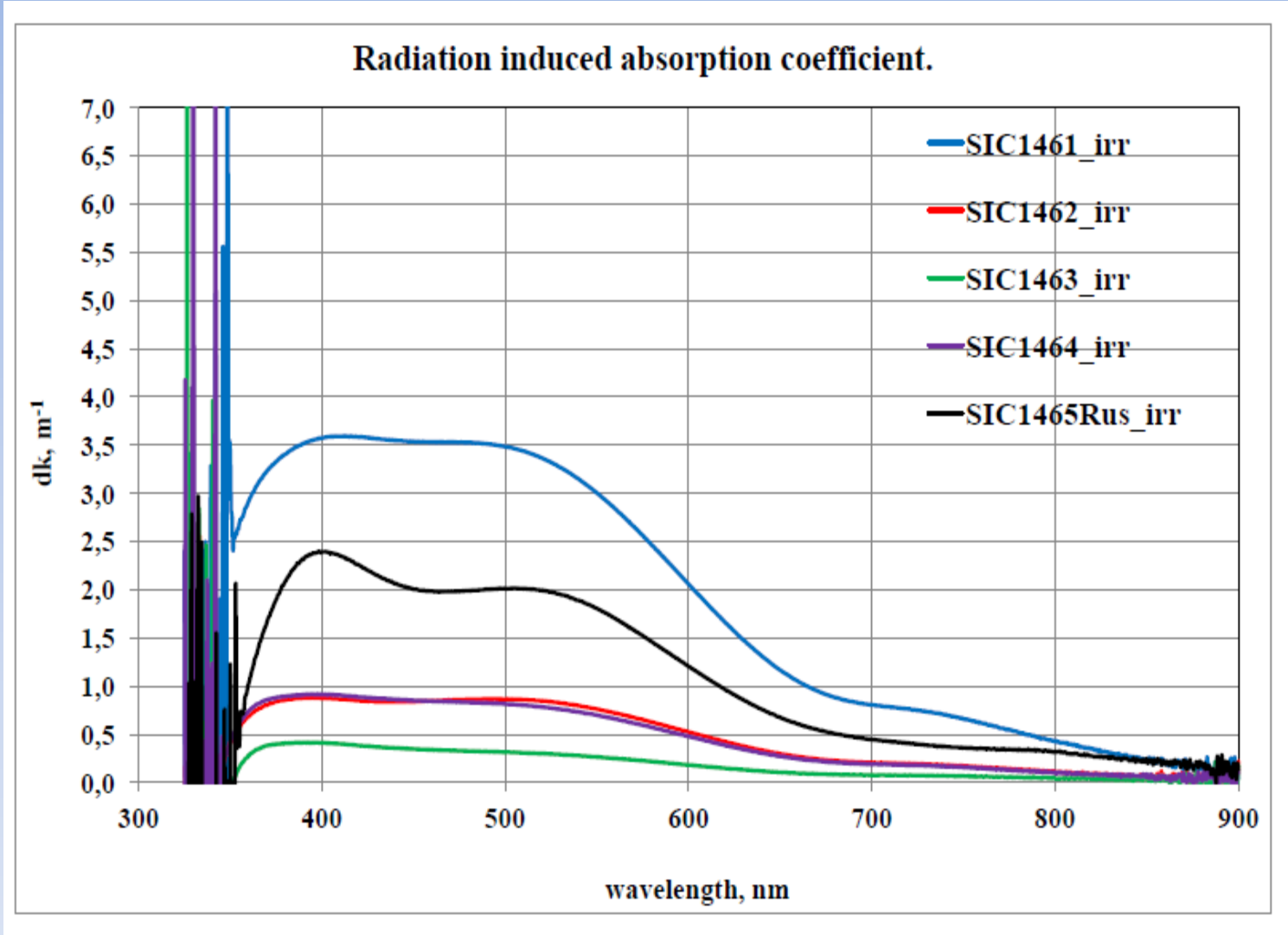
- recent delivery from SICCAS (1)

SICCAS ID	T(360	T(420	T(620	LY(T= +18 C, t=100	LY(100	dk(420 nm)	comment SICCAS	LY
	%	%	%	phe/MeV	at T=18C, %	m <sup>-1</sup>		SICCAS
<b>limits</b>	<b>≥ 35</b>	<b>≥ 60</b>	<b>≥ 70</b>	<b>≥ 16</b>	<b>&gt; 90</b>	<b>&lt; 1.1</b>		
1451	19,0	58,8	73,8	22,3	94,1	1,92		
1452	25,2	62,9	74,2	22,3	94,1	0,72		
1453	23,2	57,8	75,3	11,1	90,4	3,94		
1454	35,0	67,2	77,8	26,9	93,7	0,69		
1455 rus	10,1	52,5	73,5	15,4	93,9	2,68		
1456	2,0	56,5	73,8	15,6	90,6	6,36	doping	17,1
1457	16,4	42,3	62,9	13,1 at -25 C	87,8	6,32	doping	13,4
1458	20,4	58,8	75,2	17,8	91,3	2,93	doping	22,0
1459	11,3	52,6	68,5	19,2	92,1	2,74	doping	21,1
1460	19,1	45,7	63,6	?	?	5,89	doping and raw materia	15,4
1461	8,8	52,0	65,6	19,7	91,7	3,59	doping and raw materia	20,5
1462	32,5	60,7	74,3	21,9	91,5	0,85	doping and raw materia	17,7
1463	22,9	55,1	67,3	21,5	91,9	0,38	doping and raw materia	19,7
1464	22,7	59,0	74,1	20,5	91,6	0,89	doping and raw materia	23,9
1465 rus	1,8	40,3	66,5	12,9	90,8	2,26		9,3

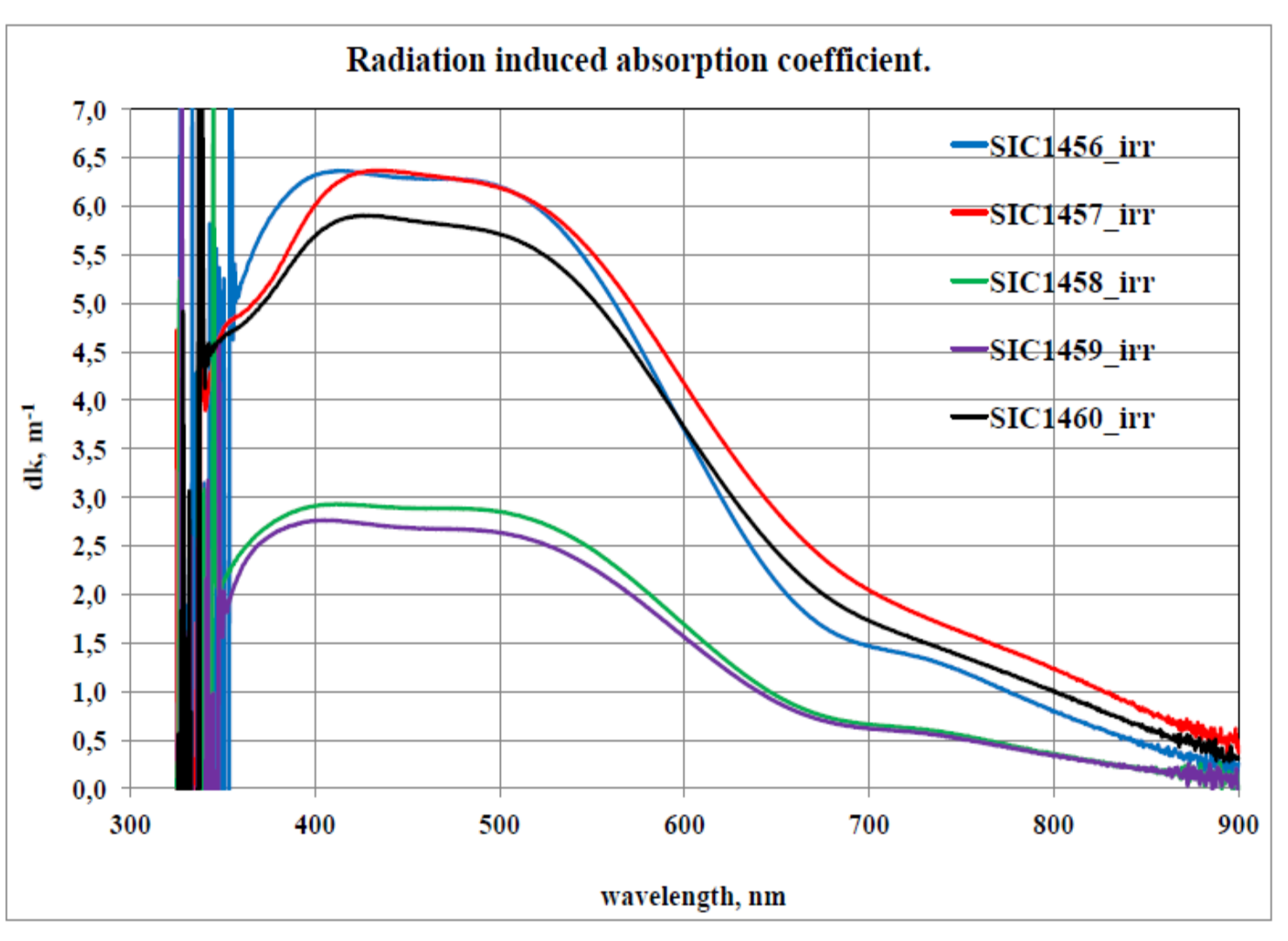
# recent delivery from SICCAS (1)



- recent delivery from SICCAS (1)



- recent delivery from SICCAS (1)



# • additional new PWO manufacturing



CRYTUR – Turnov, Czech Republic

- R&D phase just started (June 2014)
- Czochralsky technology (identical to BTCP)
- know-how and raw material still available



News (November 20, 2014)

- first good crystal grown
- test samples grown at Prague
- visit and discussion in December



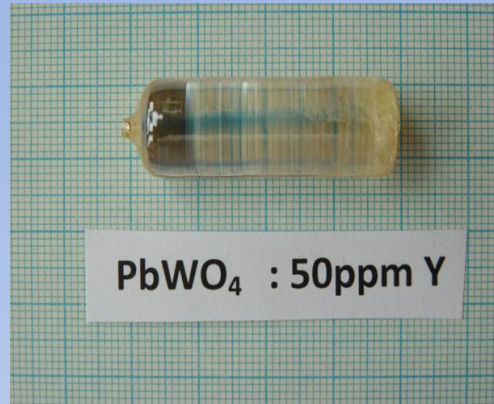


Fig. 1 (a) Photo of  $\text{PbWO}_4$  crystal grown in oxygen-free atmosphere.  
(b) 50 ppm Y doped grown in air;  
(c) La+Y doped grown in  $\text{N}_2+0.1\%\text{O}_2$  atmosphere

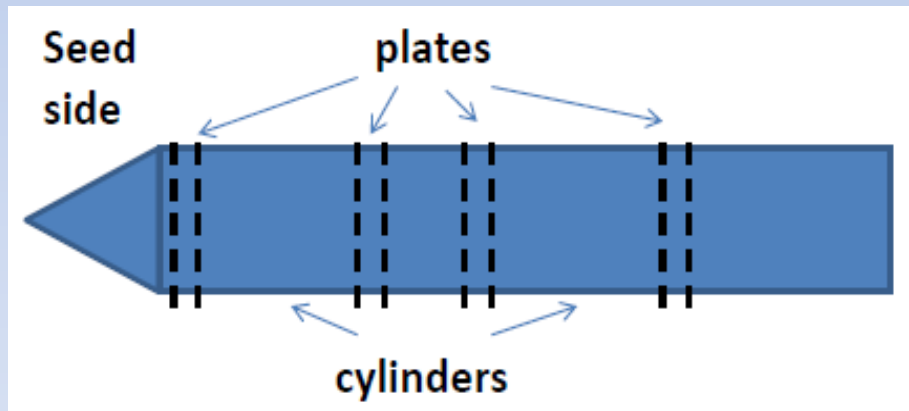
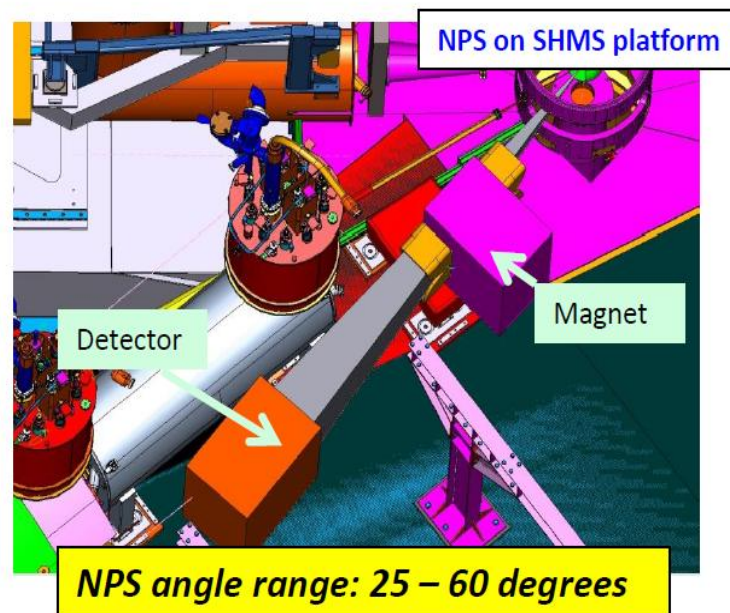
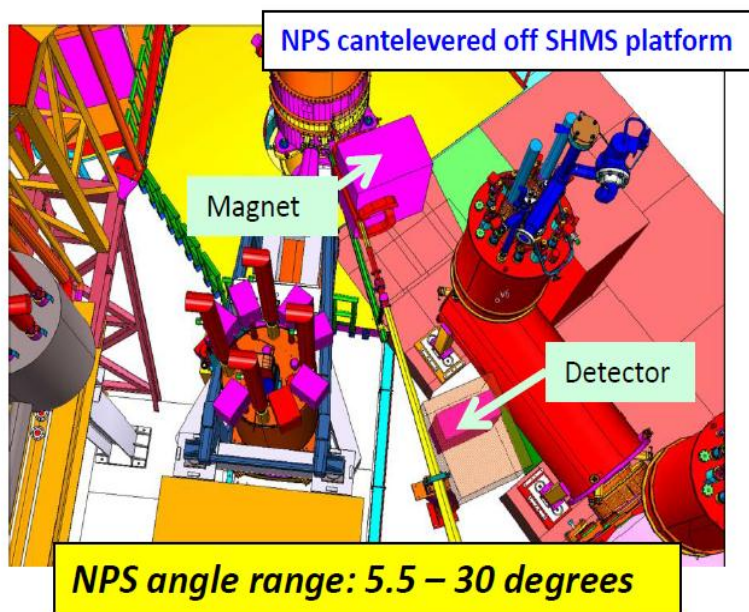


Fig. 2 Sketch of the  $\text{PbWO}_4$  crystal cut



# The Neutral-Particle Spectrometer (NPS)

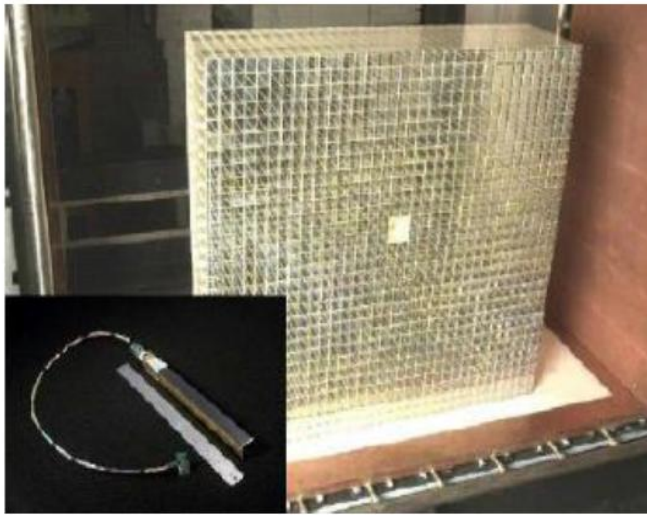
The NPS is envisioned as a facility in Hall C, utilizing the well-understood HMS and the infrastructure of the new SHMS, to allow for precision (coincidence) cross section measurements of neutral particles ( $\gamma, \pi^0$ ).



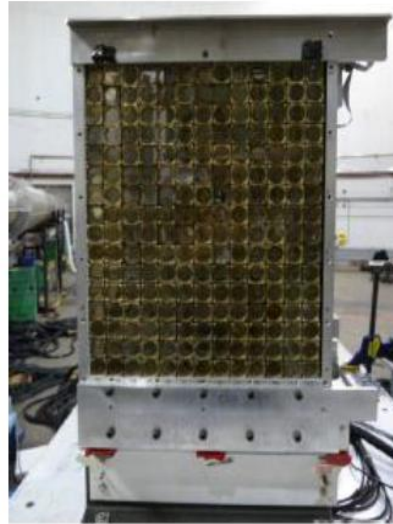
## Scientific Program:

- ❑ E12-13-010 Excl. Deeply Virtual Compton and  $\pi^0$  Cross Section Measurements (**approved** by PAC40)
- ❑ E12-13-007 Measurement of SIDIS  $\pi^0$  production as Validation of Factorization (**approved** by PAC40)
- ❑ PR12-13-009 Wide-Angle Compton Scattering (WACS) at 8 & 10 GeV Photon Energies
- ❑ LOI12-13-003 Exclusive Photoproduction of  $\pi^0$  mesons at large angles (positive comments at PAC40)

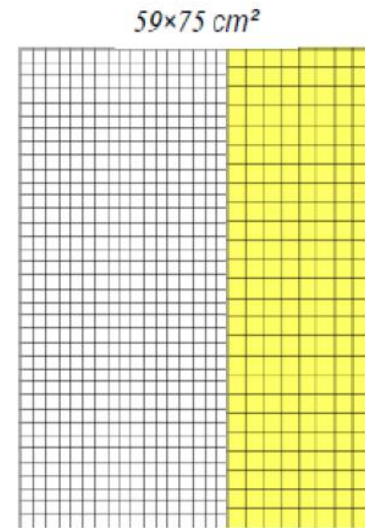
# NPS Crystal Matrix



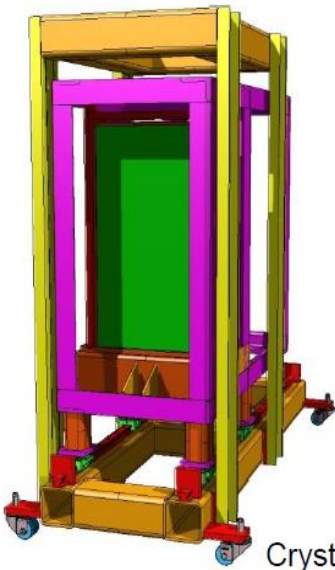
High resolution  $\text{PbWO}_4$  part from HyCAL



DVCS/Hall A  $\text{PbF}_2$  calorimeter



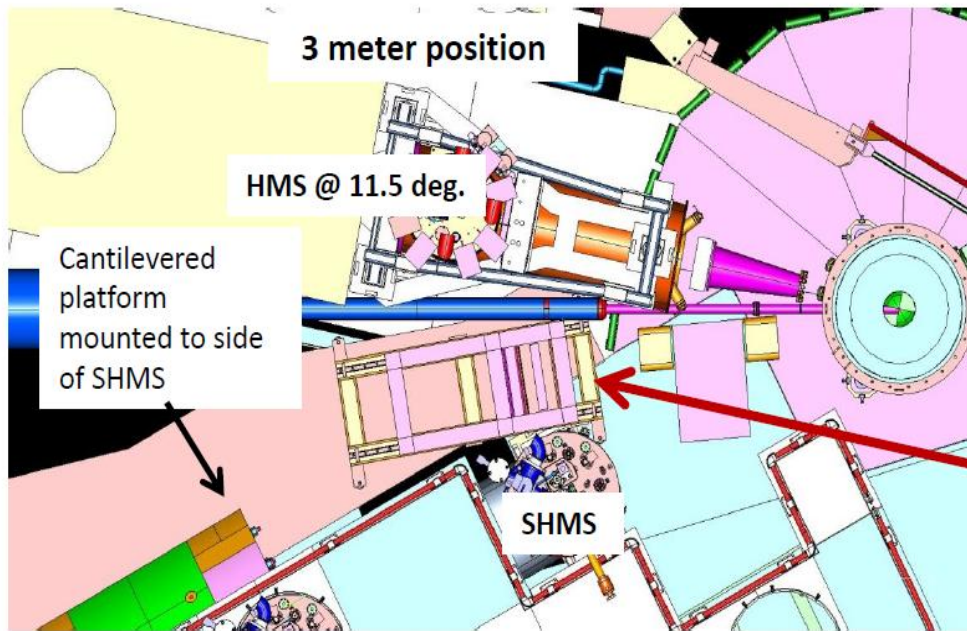
$59 \times 75 \text{ cm}^2$   
 $612 \text{ PbWO}_4 + 200 \text{ PbF}_2$   
NPS hybrid crystal matrix



Crystal matrix in NPS frame

- In ideal conditions would start with brand new  $\text{PbWO}_4$
- Taking advantage of existing  $\text{PbWO}_4$  crystals from HyCAL, one arrangement is in a  $36 \times 30$  matrix covering 25 msr at distance of 4 m from target ( $\sim 1100$  crystals)
- Could use  $\text{PbF}_2$  crystals from DVCS/Hall A to fill out solid angle if only  $\sim 600 \text{ PbWO}_4$  available

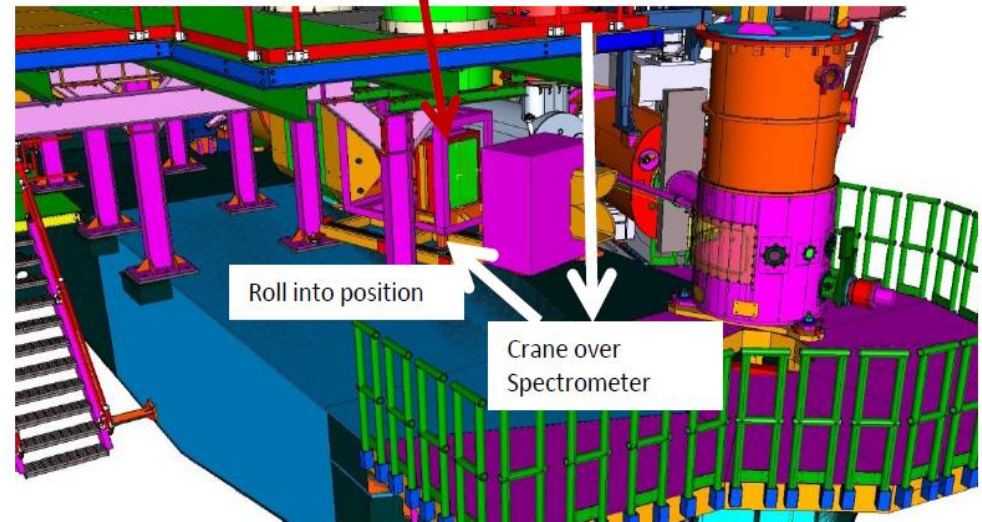
# NPS Frame



- NPS frame mounted on base frame with rail system allowing for movement in z to positions between 3 m and 12 m from the target

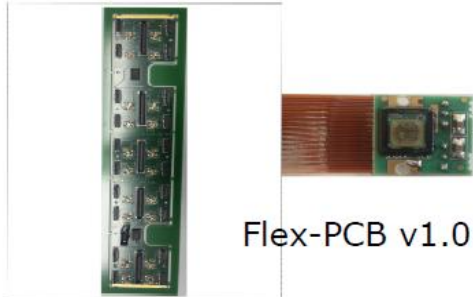


- For experiments like Wide Angle Compton Scattering requiring angles  $\geq 25$  degrees NPS can be installed on the other side of the SHMS



# Readout Electronic – PCBs

2012



Flex-PCB v1.0

Backplane v1.0

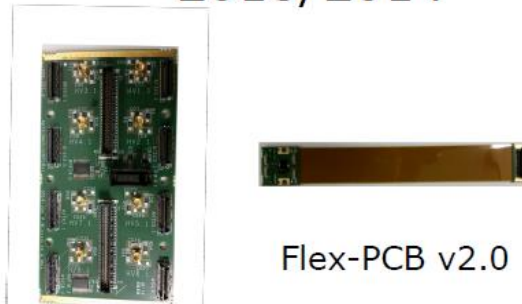
## Backplane v1.0:

- Design: 2 x 10 ASICs
- Fits to the Proto 120 geometry
- Complex programming structure
  - Chip ID 1 ..16

## Flex-PCB v1.0:

- Not shielded rigid flex PCB
  - pick-up noise
- One HV for both channels
- Only one GND!
- No HV blocking on the flex PCB

2013/2014



Flex-PCB v2.0

Backplane v2.0

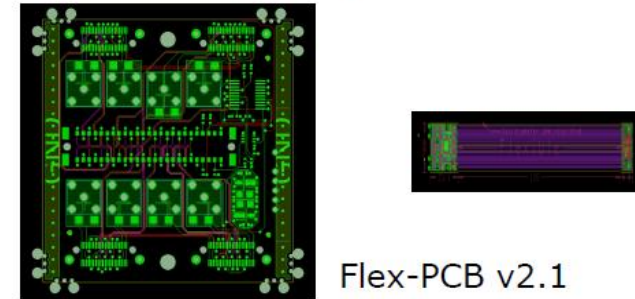
## Backplane v2.0:

- Design: 2 x 4 ASICs
- Not forseen for the Proto 120 geometry
  - only for lab tests
- Simple programming structure
- One HV for two channels

## Flex-PCB v2.0:

- Bouth side shielded rigid flex PCB
- One HV for both channels
- Only one GND!
- HV blocking close to the APD region

2014/2015



Flex-PCB v2.1

Backplane v3.0

## Backplane v3.0:

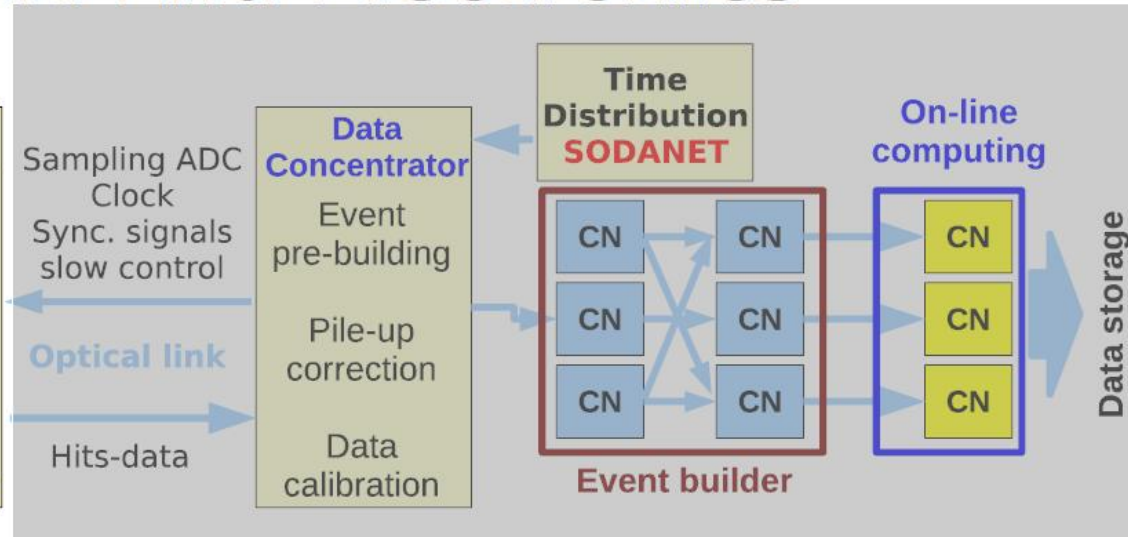
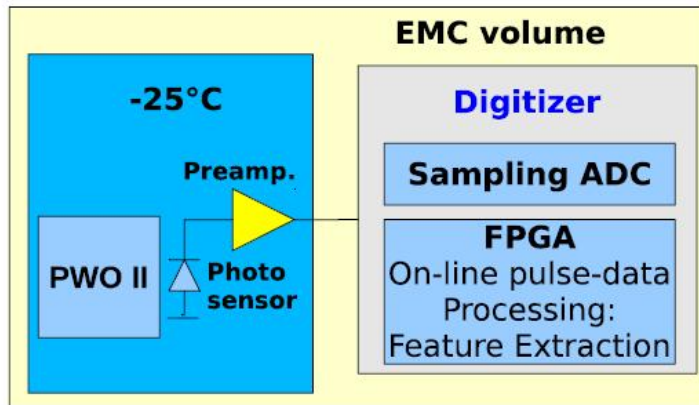
- Design for only 2 x 2 ASICs
- Fits to the Proto 120 geometry
- Simple programming structure
- One HV for each channel!!!
- Separate HV GND

## Flex-PCB v2.1:

- Double side shielded rigid flex PCB
- HV separate for each channel
- HV blocking close to the APD region

# EMC Front-End Electronics

## Intelligent front-end electronics



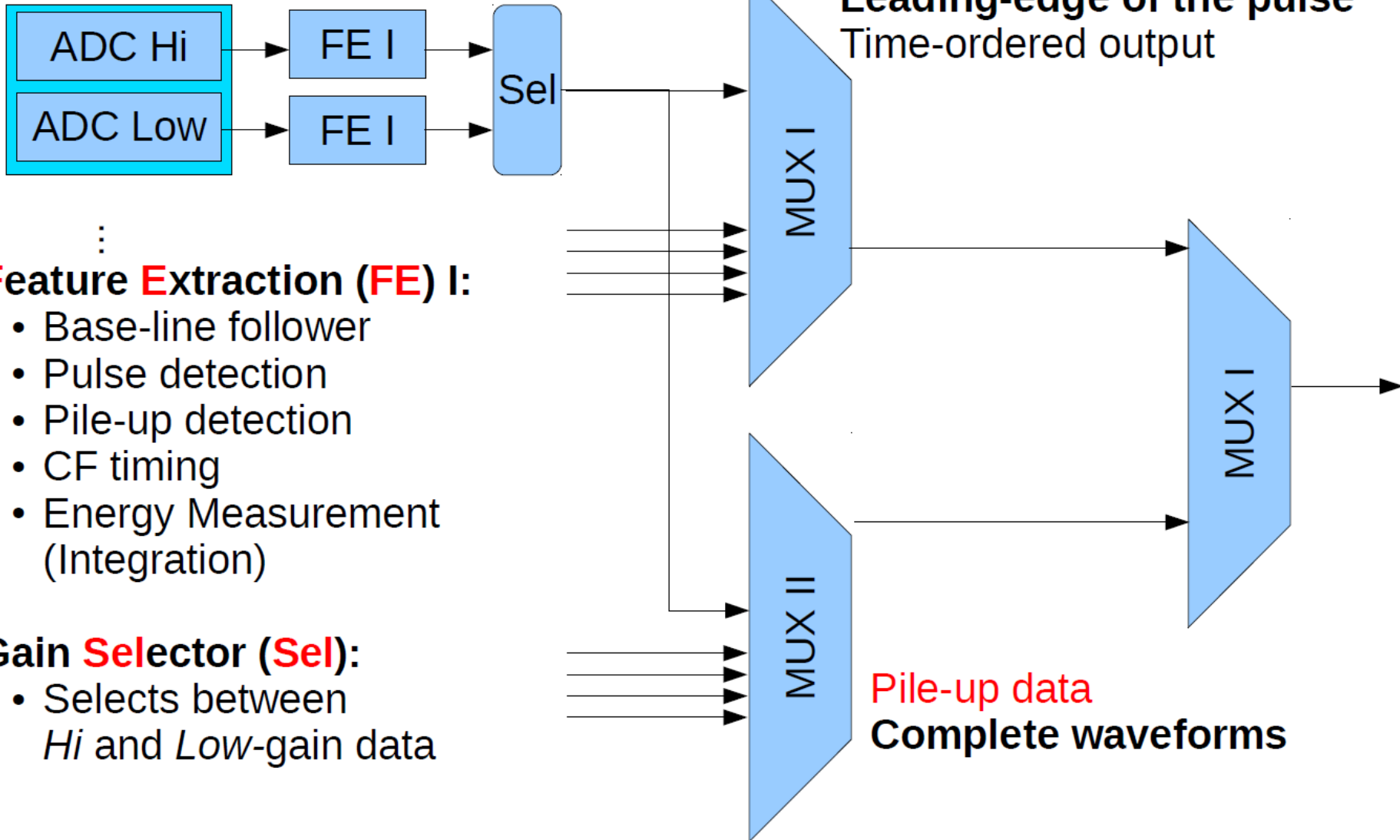
## EMC digitizer:

- 64 ADC channels (32 dual-gain readout channels)
- 14 bit resolution
- 80-125 MHz sampling rate
- On-line detection of hits, extraction of hit information, pulse pile-up recovery by two Xilinx Kintex-7 FPGAs

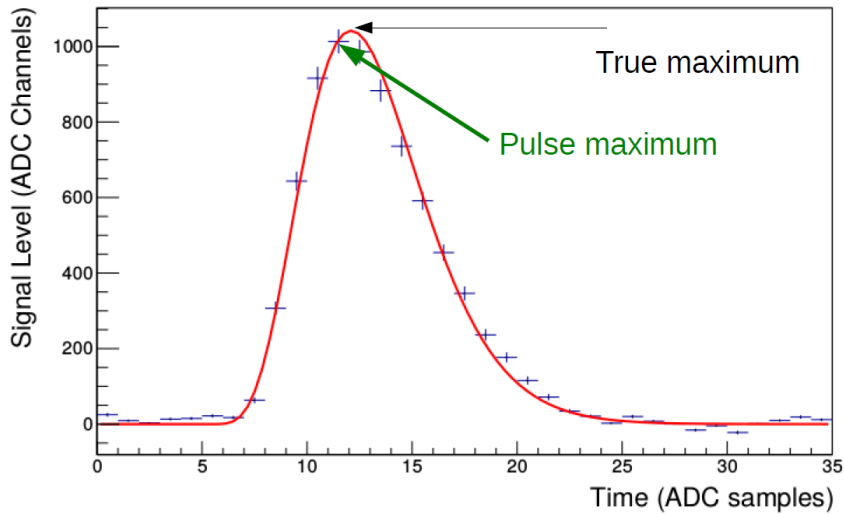
Digitizers are located in radiation area → precautions have to be taken against configuration changes and SEU in FPGAs

# Feature-Extraction Algorithm

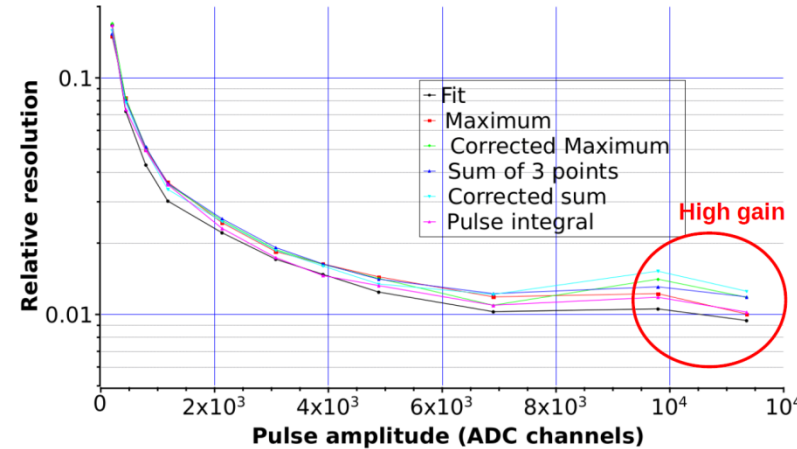
[Developed at KVI-CART]



# Precise Amplitude Measurement

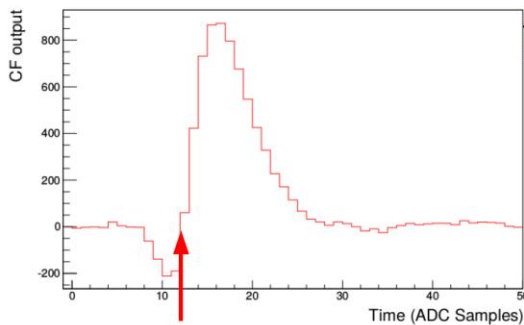


# The Best "Energy" Measurement



Integration – the best option?

# Time Measurement



Analogue-like implementation:

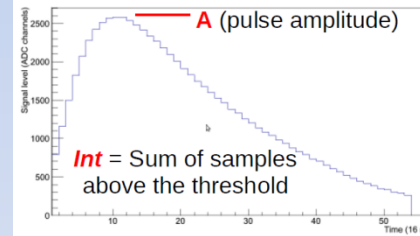
$$CFT(n) = MWD(n-d) - R \cdot MWD(n)$$

- Delay  $d$  = signal rise time
- Fraction  $R$  - to select most linear part of the signal leading edge ( $R=1/4$ )
- $N$  - number for the linear regression
- Symmetry against zero level

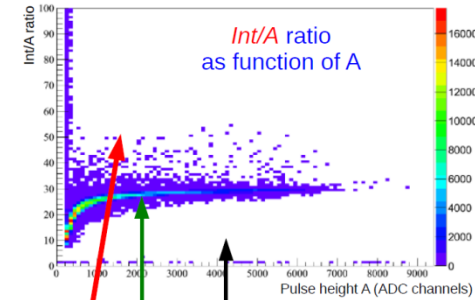
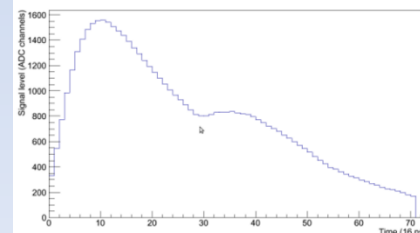
Time stamp: zero-crossing (linear regression)

# Pile-up Detection

If samples above threshold satisfy  $Int/A$  criterion → Pulse is detected



Pile-up event identified on-line



Pulse-detection works properly:

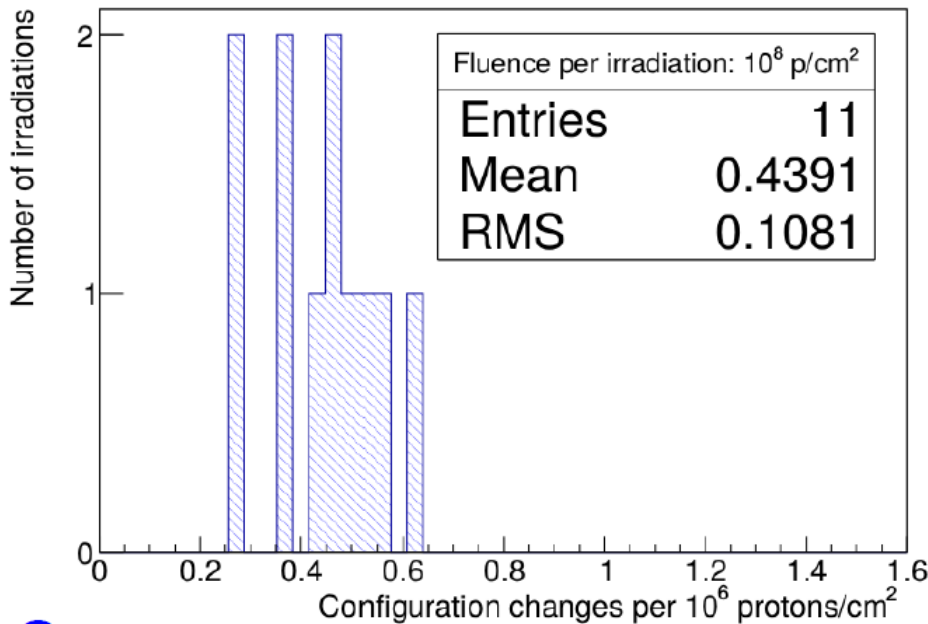
- Detection of single pulses
- Detection of pile-up structures

# Irradiation of Kintex-7 (XC7K325T)

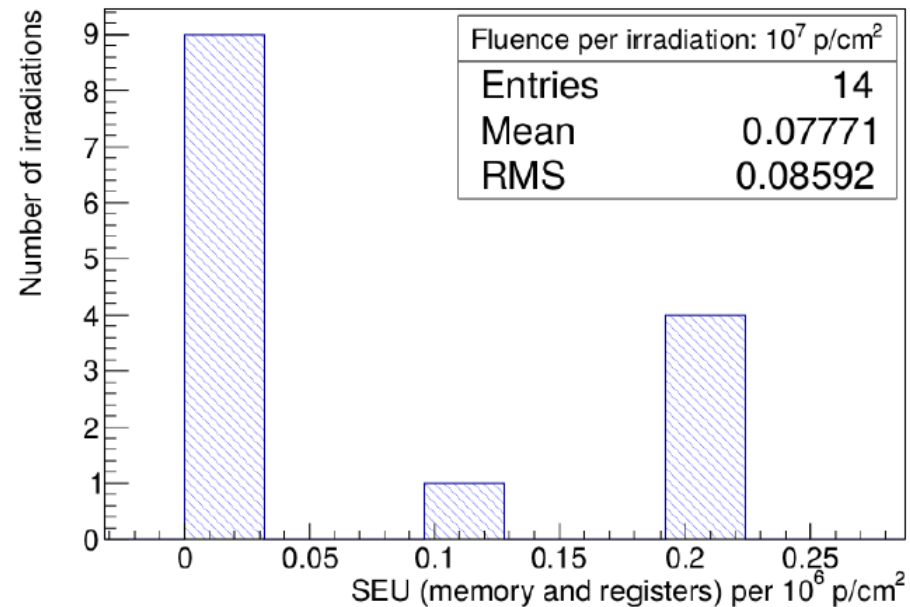
150 MeV protons, homogeneous field

Resources involved in the SEU test: Registers: **54%** ( $=2.2 \cdot 10^5$ )  
Block RAM: **86%** ( $=1.4 \cdot 10^4$  kb)

Configuration changes per  $10^6 / \text{cm}^2$



SEU per  $10^6 / \text{cm}^2$



**On average:**

configuration changes:  
0.44(11) per  $10^6 / \text{cm}^2$

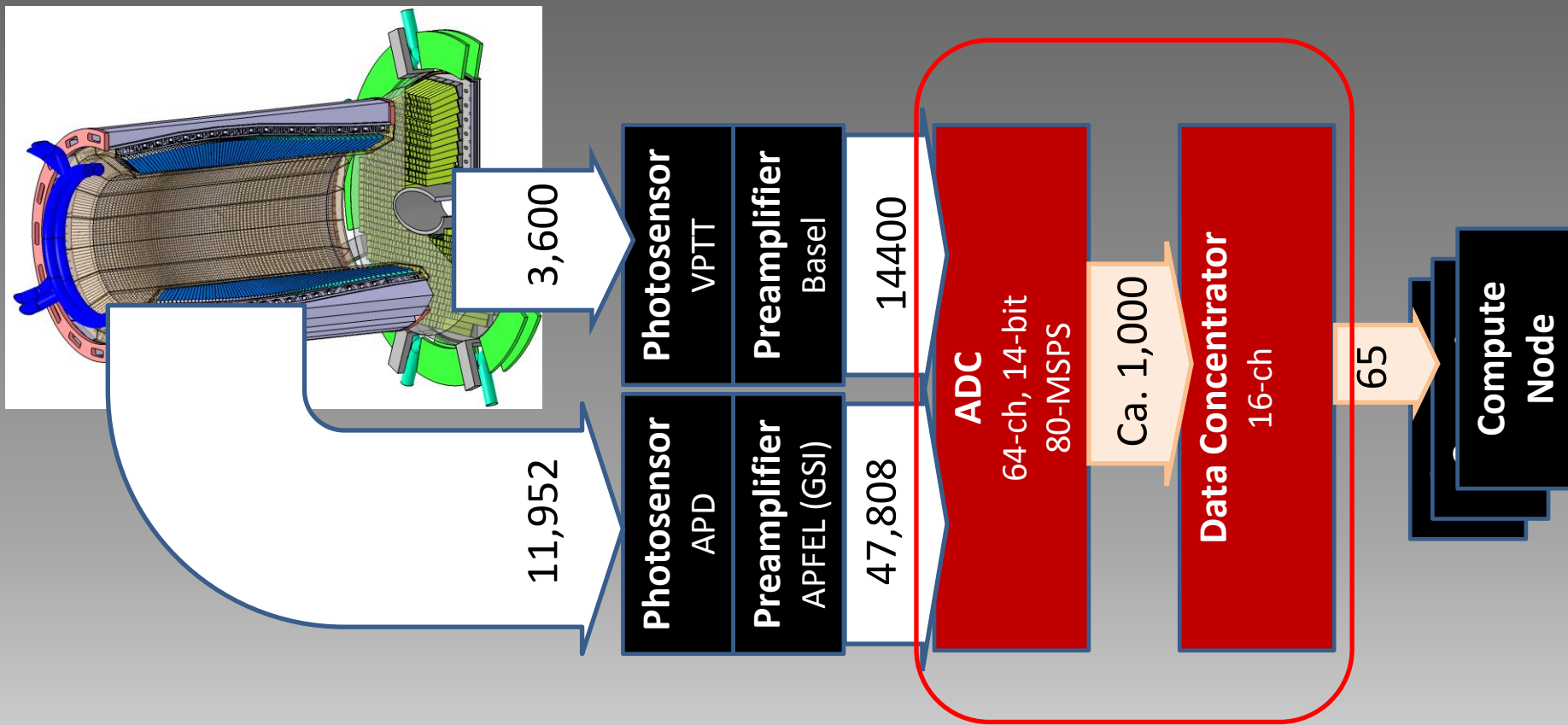
SEU events:  
0.08(8) per  $10^6 / \text{cm}^2$

**→54 min operation without reconfiguration (incl. safety factor 10)**





# - PANDA EMC Readout System



# - SADC development for PANDA



**2008**

16-ch, 12-bit  
160 MSPS ADC  
Used for the  
first tests, sold  
to WIENER

**2010**

16-ch, 2Gbit/s  
Optical Data  
Concentrator  
Used in many  
experiments  
including  
WASA, KLOE2

**2011**

16-ch, 14-bit  
125 MSPS ADC  
Virtex-5  
Used for  
evaluation of  
DSP algorithms

**2012**

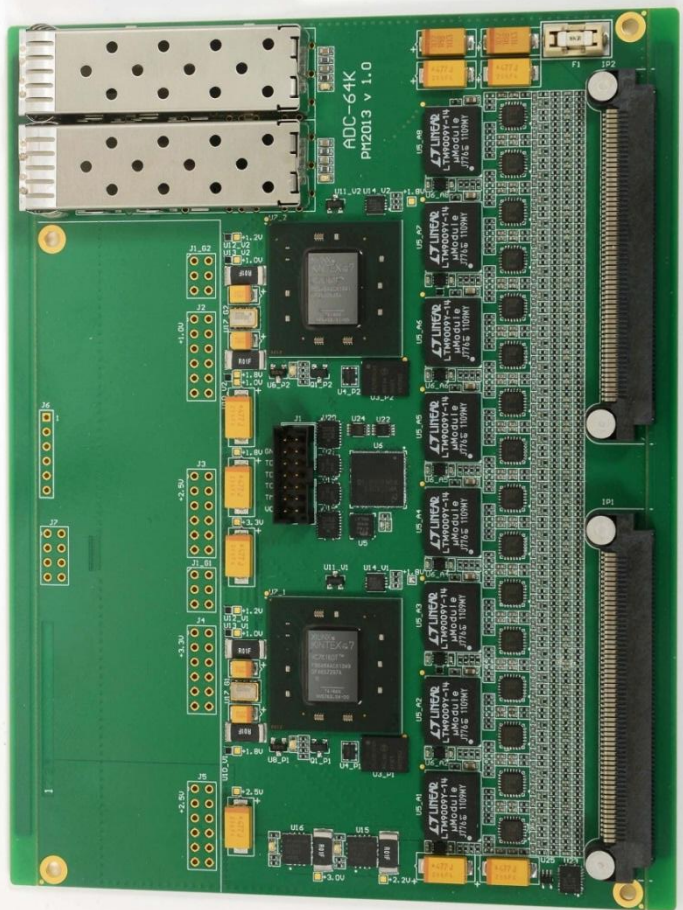
32-ch, Dual-  
range, 14-bit  
80 MSPS ADC  
Virtex-6  
Used for first  
data taking and  
durability tests

**2013**

64-ch, 14-bit  
80 MSPS ADC  
Kintex-7  
Close-to-final  
prototype

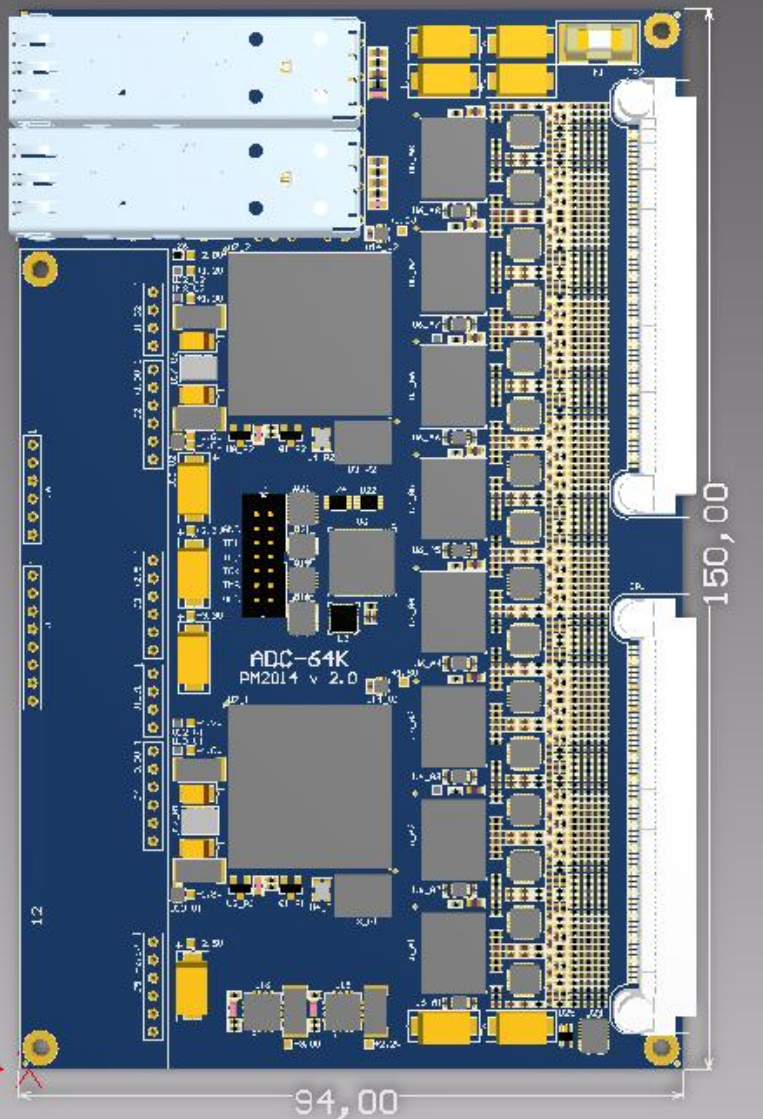


# ADC for EMC - ADC\_64K



ADC Model	ADC_32DR	ADC_64V	ADC_64K
No. of channels	32 (64)	64	64
Sampling rate	80-125 MSPS		
Input coupling	DC, positive, negative, diff		
Resolution (ampl)	14-bit dual range	14-bit	
Input Connector	uFL	Samtec	
Baseline	0V		
Input range (dual)	±1.0V, ±60 mV	±1.0V, ±100 mV	
Noise	100uV		
Data retention/ch.	25us		
Input filter	Active-filter/Amplifier	CR-passive	Active filter/Amplifier
Interface	Optical, SFP, LC-type, 2 Gbit/s		
Feature extraction:			

## ADC\_64K\_2



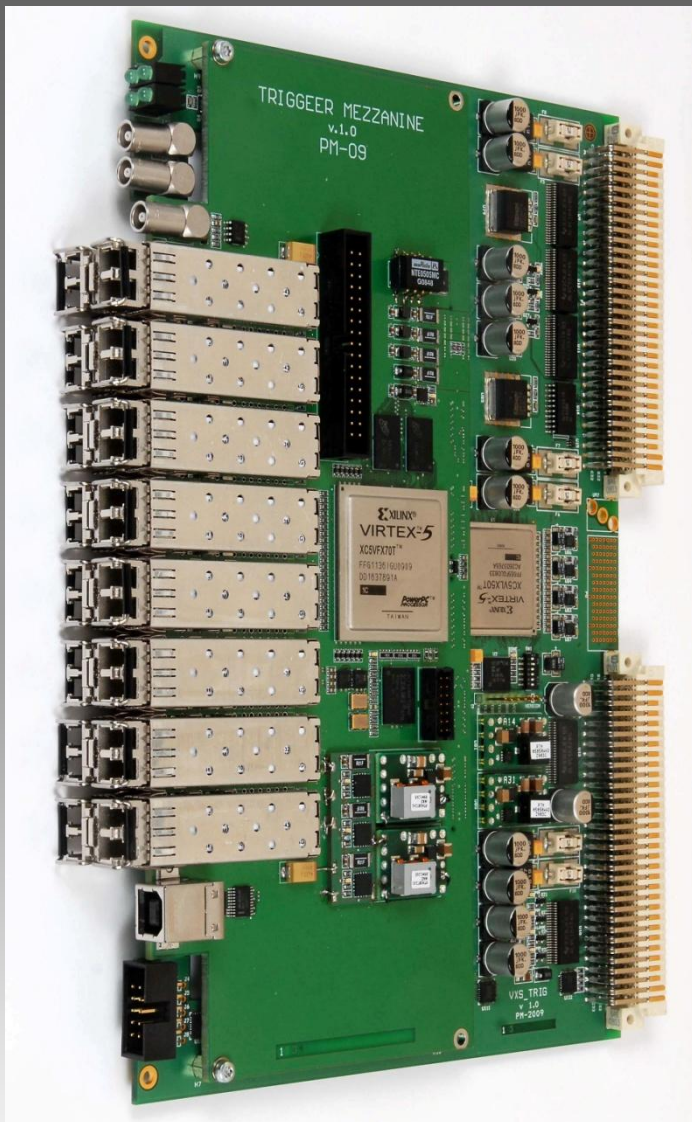
## List of recent changes/improvements

1. Overall error correction
2. Input can be galvanically de-coupled from the ground
3. Improved analog/digital ground separation
4. All low-voltage power supplies can be distributed via backplane connectors
5. Space optimization
6. Baseline shifting (?)

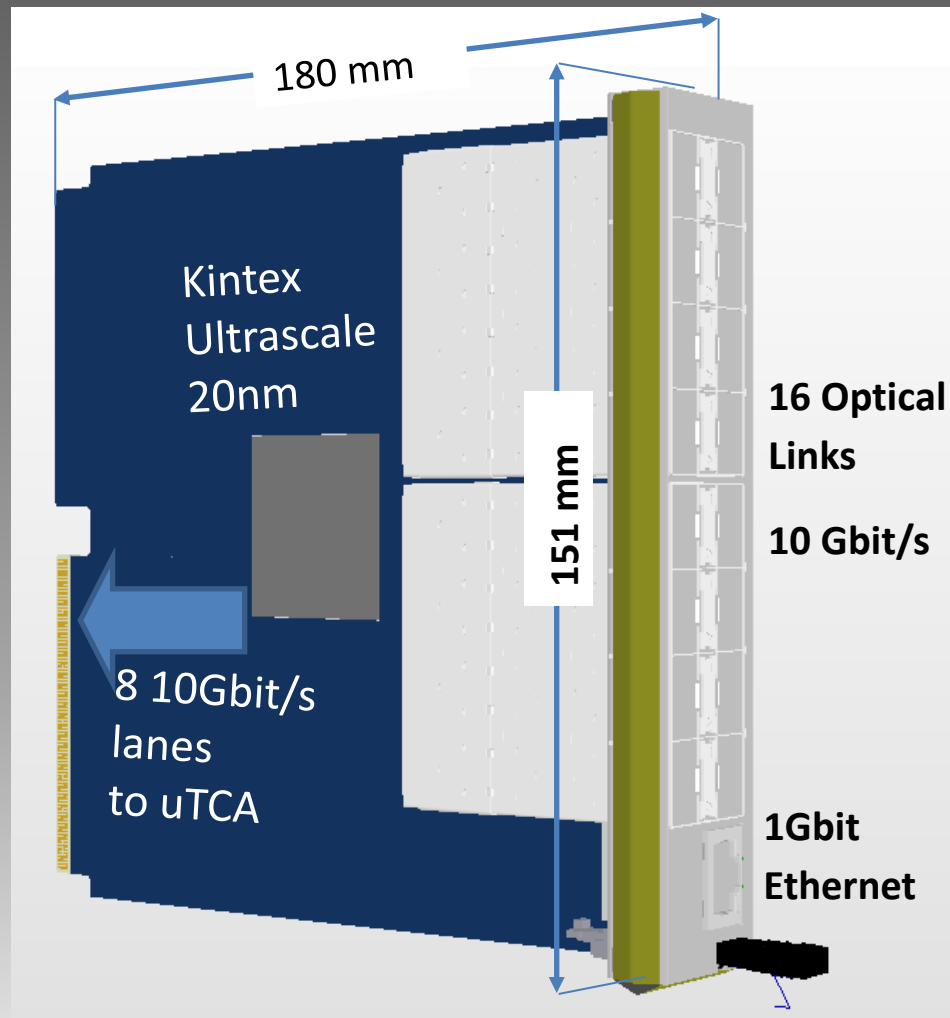


# - Data Concentrators

VME64x

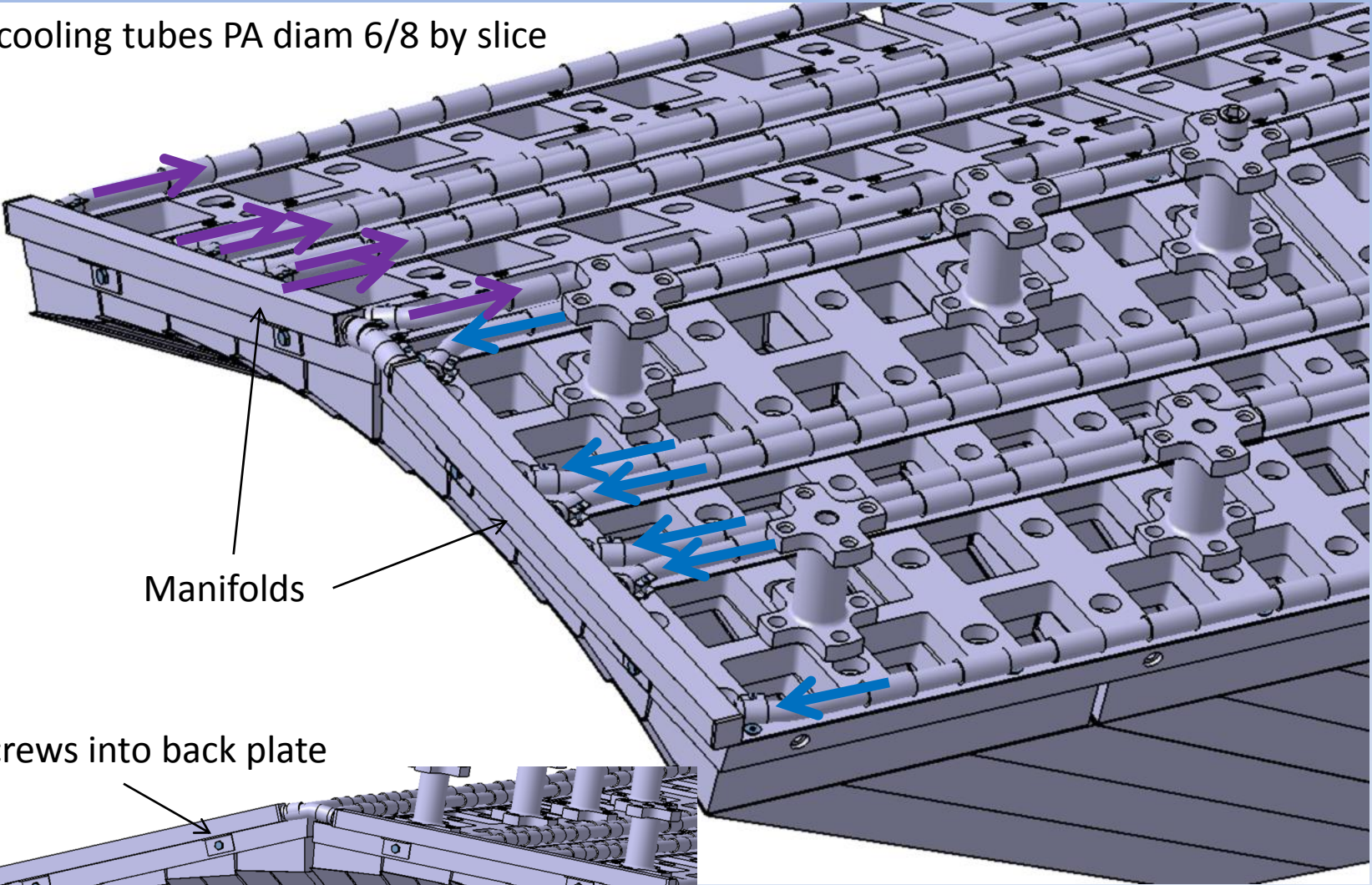


AMC (uTCA)



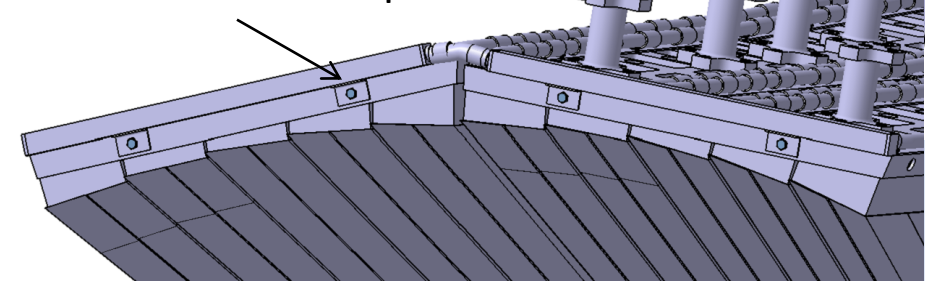
# Forward extremity

6 cooling tubes PA diam 6/8 by slice

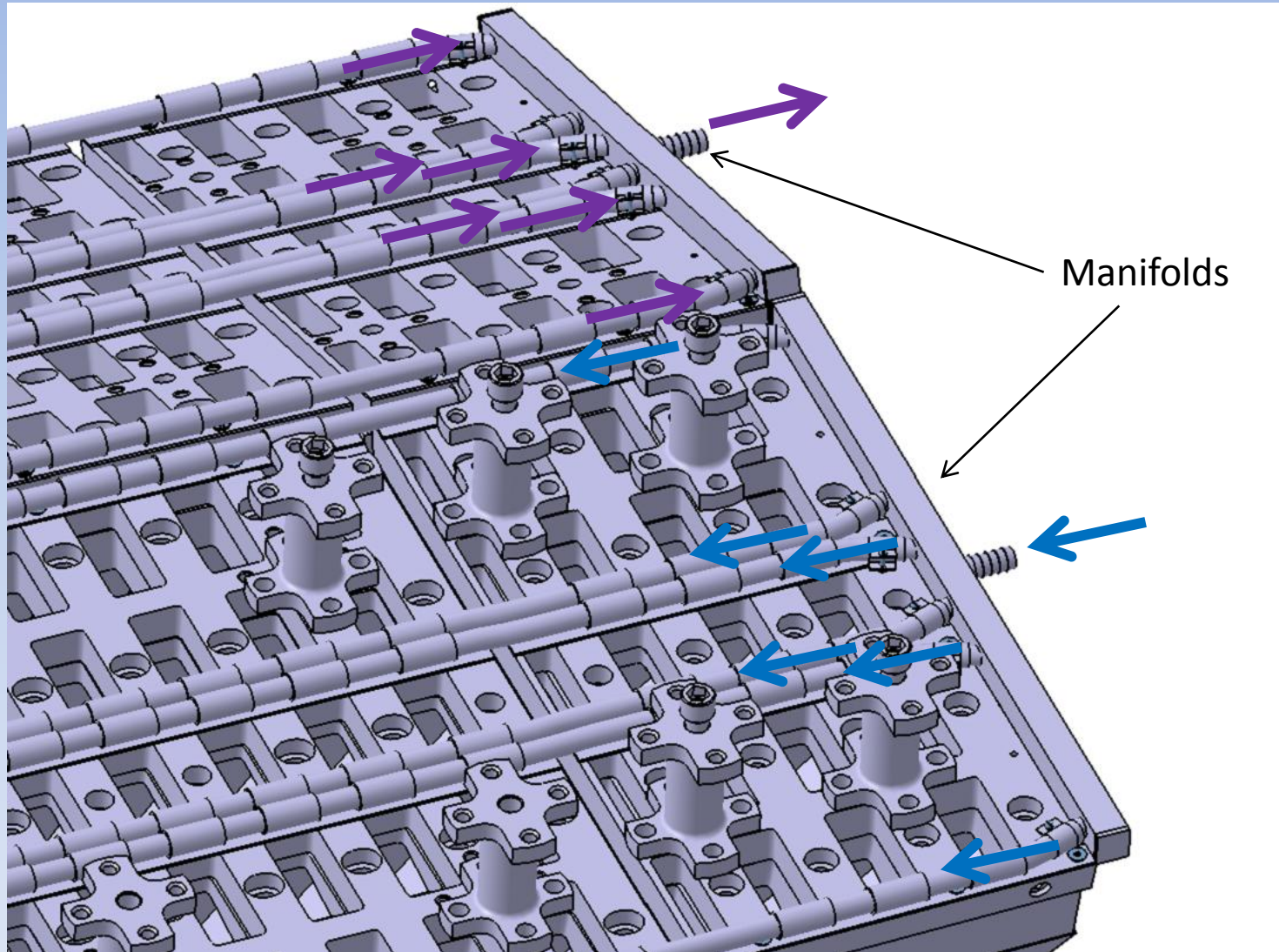


Manifolds

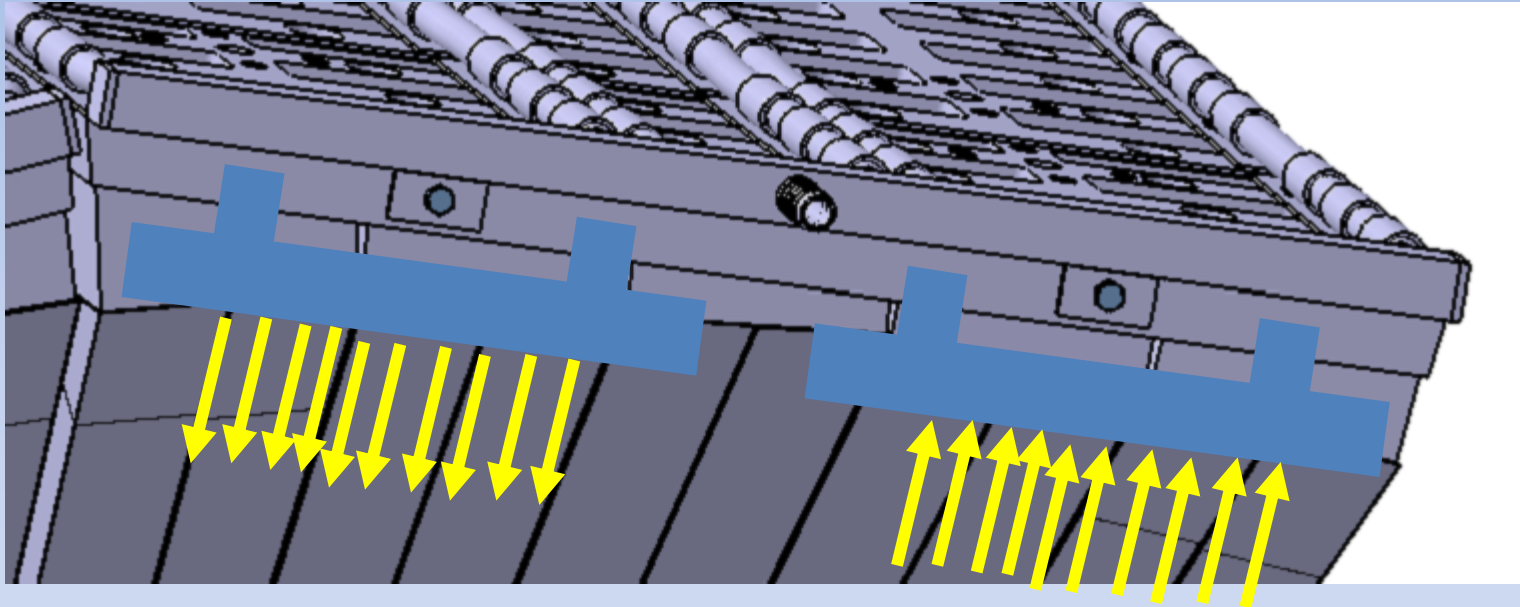
Screws into back plate



# Backward extremity



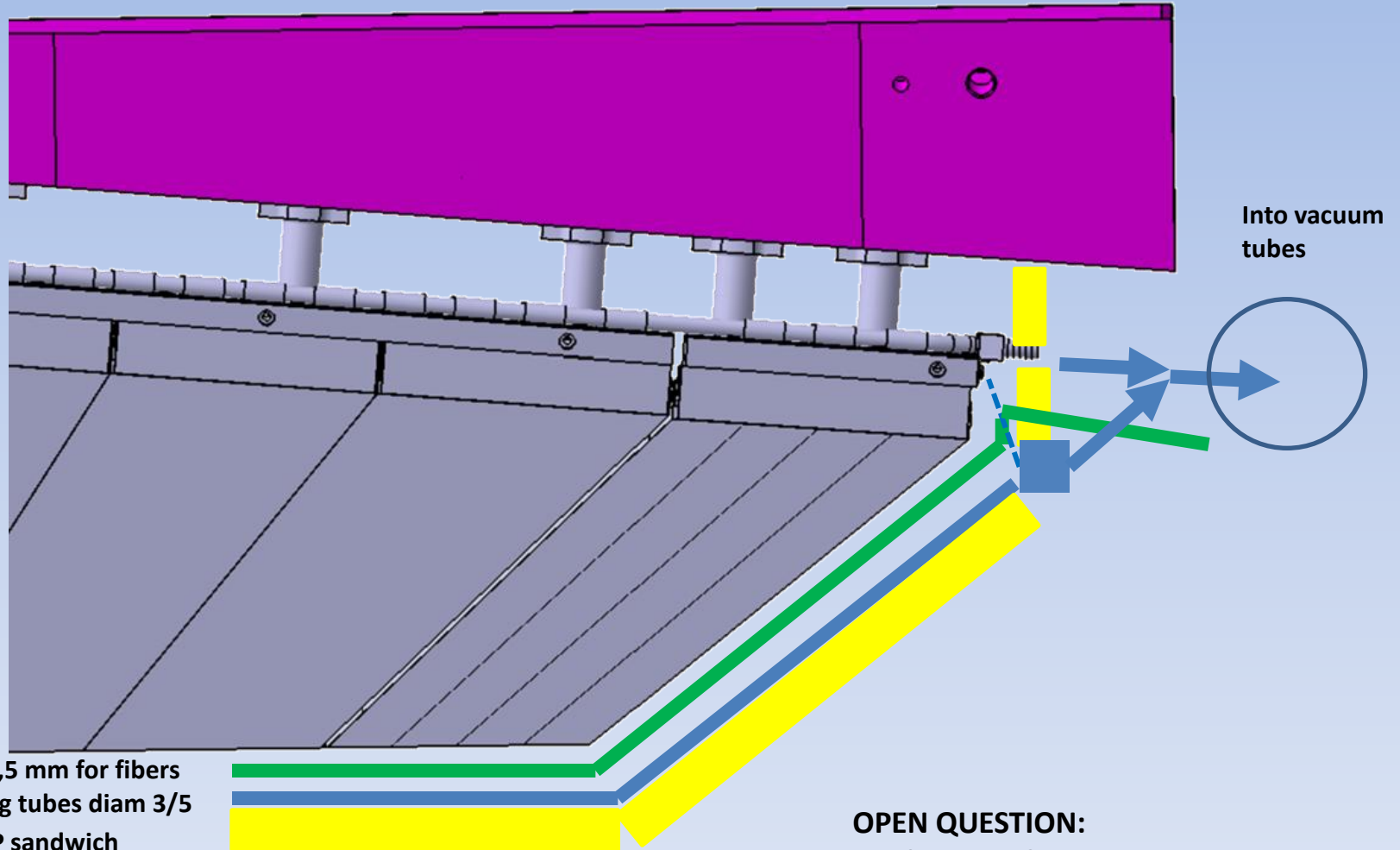
## Backward extremity



Manifolds for front crystals cooling fixed also on back plate  
2x10 cooling tubes PA diam 3/5



# Backward extremity



Into vacuum tubes

2,5 mm for fibers  
20 cooling tubes diam 3/5

VIP sandwich

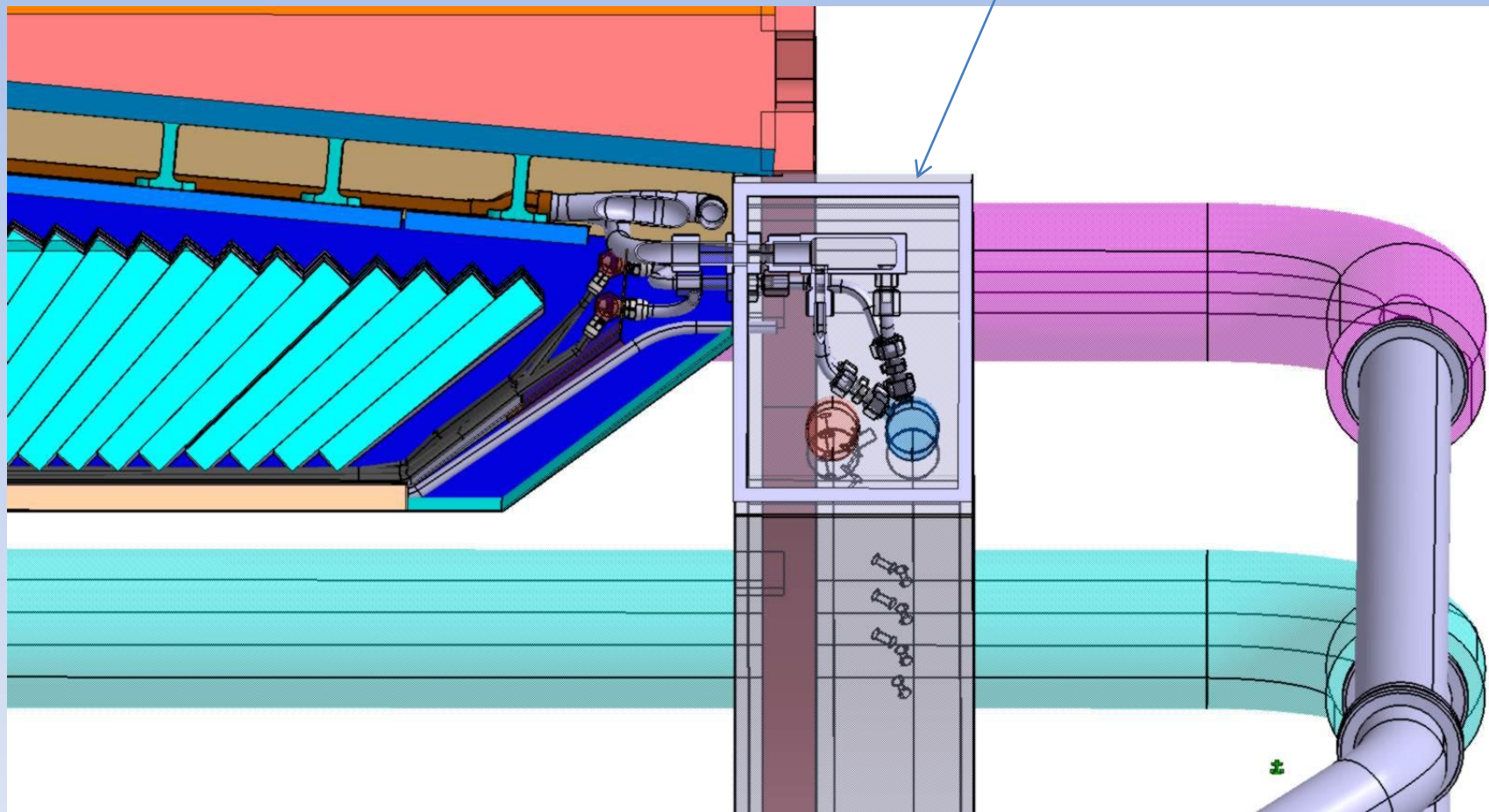
1 mm thermal resistance in front – 0,5 mm aluminium – 15 mm VIP – 0,5 mm carbon – 5 mm tubes

**OPEN QUESTION:**

- Fibers out ?
- Thermal sensors out ?

# Vacuum box for cooling tubes going out of the barrel

To be defined in spring (other training student  
(Christopher paid by Giessen))

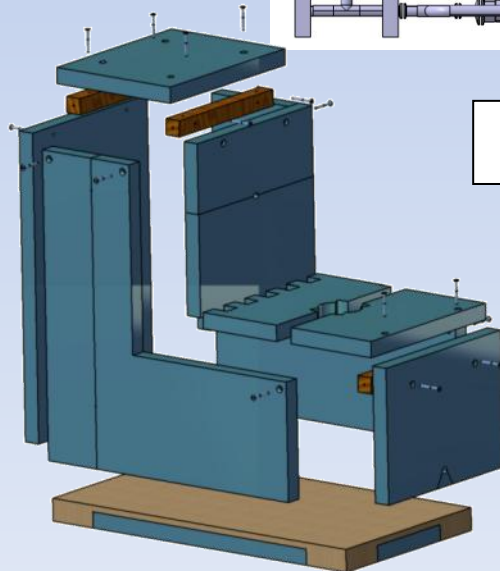
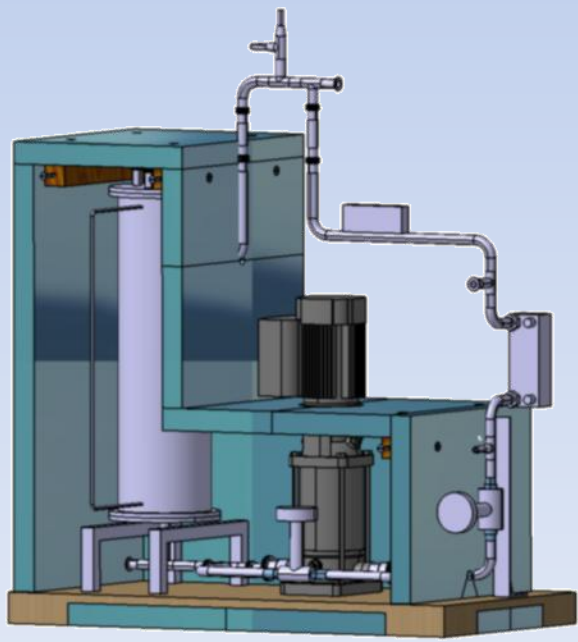
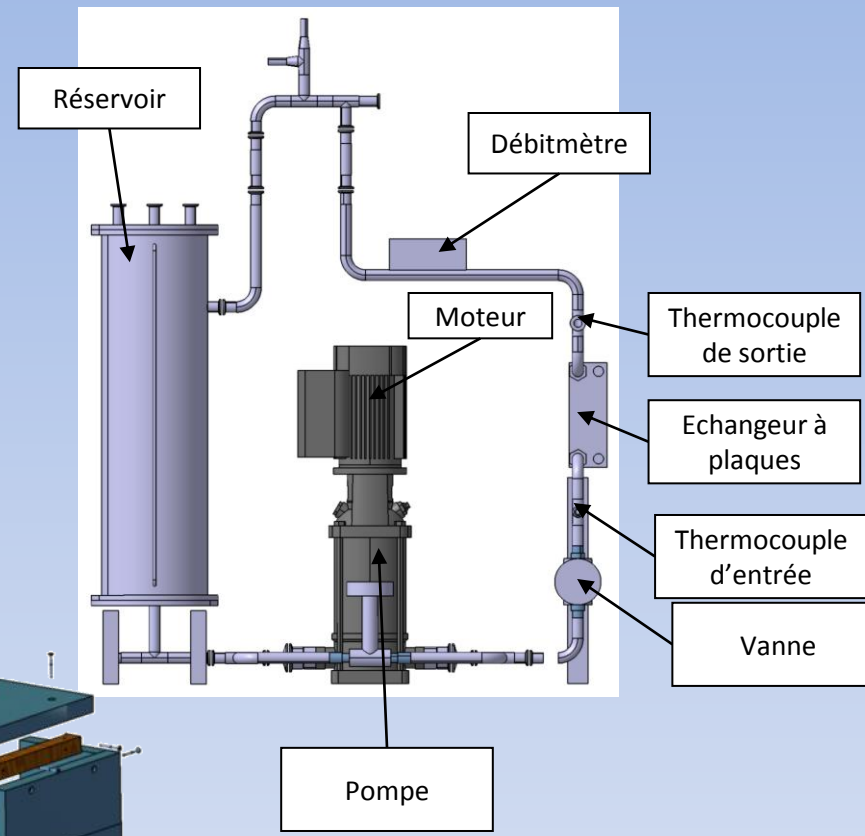


# Pump insulation

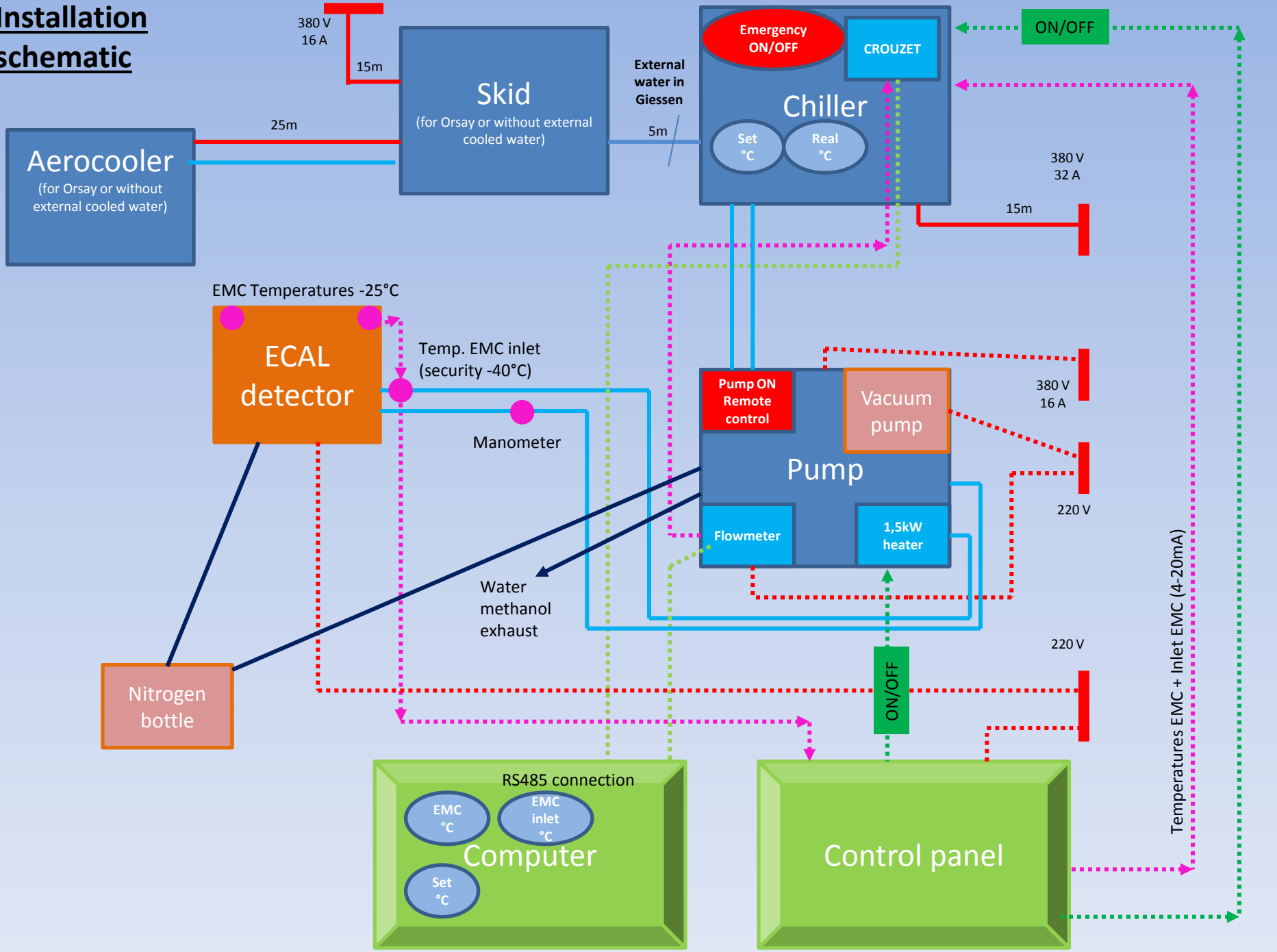
(with flowmeter – vacuum – tank – manometer – 1,5kW heater)

But : Isoler l'ensemble pompe réservoir déjà existant.

Dessiner l'enceinte en Roofmate.



# Installation schematic




# Cables


## Cables

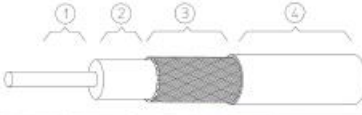
from patch panel  
PCB to the outside:

- Huber+Suhner Enviroflex (HV)
- Nexans Filotex (signal) yields attenuation of preamp pulses by 0.18 dB/m
- Ribbon (sensor) + LV cables



Technical Data	
<b>Construction</b>	
Centre conductor	Steel, Copper-Silver plated
Dielectric	PTFE (Polytetrafluorethylen.)
Outer conductor	Copper, Silver plated
Jacket	FEP (Fluorethyene Prop.)
Print	HUBER+SUHNER RG 178 BIU 50 Ohm (PA no.)
<b>Electrical Data</b>	
Impedance	50 $\Omega$ +/- 2
Max. operating frequency	1 GHz
Capacitance	96.8 pF/m
Velocity of signal propagation	69 %
Signal delay	4.84 ns/m
Insulation resistance	21 x 10 <sup>12</sup> M $\Omega$ m
Min. screening effectiveness	>40 dB (up to 1 GHz)
Max. operating voltage	1 kV <sub>rms</sub> (at sea level)
Test voltage	2 kV <sub>rms</sub> (50 Hz/1 min)
<b>Mechanical Data</b>	
Weight	0.84 kg/100 m
Min. bending radius	10 mm
	repeated (for max. 50 bendings) 20 mm



	<b>① Conductor :</b> 1 x 0.17 mm solid silver plated copper covered steel	<b>Electrical characteristics</b> <ul style="list-style-type: none"><li>■ Voltage rating: 250 Volts (RMS)</li><li>■ Operating temperature: -90°C to +200°C</li><li>■ Operating frequency: up to 3 GHz</li><li>■ Impedance: 50 ± 5 <math>\Omega</math></li><li>■ Capacitance: 85 pF/m</li><li>■ Relative propagation velocity: 69.5 %</li><li>■ Attenuation at<ul style="list-style-type: none"><li>0.5 GHz 1.5 dB/m</li><li>1.0 GHz 2.3 dB/m</li><li>1.5 GHz 2.9 dB/m</li><li>2.0 GHz 3.4 dB/m</li><li>3.0 GHz 4.3 dB/m</li></ul></li></ul>
	<b>② Insulation :</b> Extruded PTFE $\varnothing = 0.52 \pm 0.05$ mm	
	<b>③ Shield :</b> 0.05 mm silver plated copper braid	
	<b>④ Jacket :</b> FEP $\varnothing = 1.17 \pm 0.05$ mm	
		<b>Physical characteristics</b> <ul style="list-style-type: none"><li>■ Very good resistance to solvents</li><li>■ Very good resistance to soldering operations</li><li>■ Nominal weight : 3 g/m</li></ul>

# Summary

Measured cable length:

- HV (Huber+Suhner Enviroflex): 13606 m → 16 km ordered
- Ribbon cable: 423 m
- Signal (Nexans Filotex): 11554 m → 12 km ordered

Work in progress:

- Finalize LV cables + routing
- Design of backplate frame cable feedthrough

To do:

- Fix crate positions

# Alarm notifications for the $\bar{P}$ ANDA Detector Control System

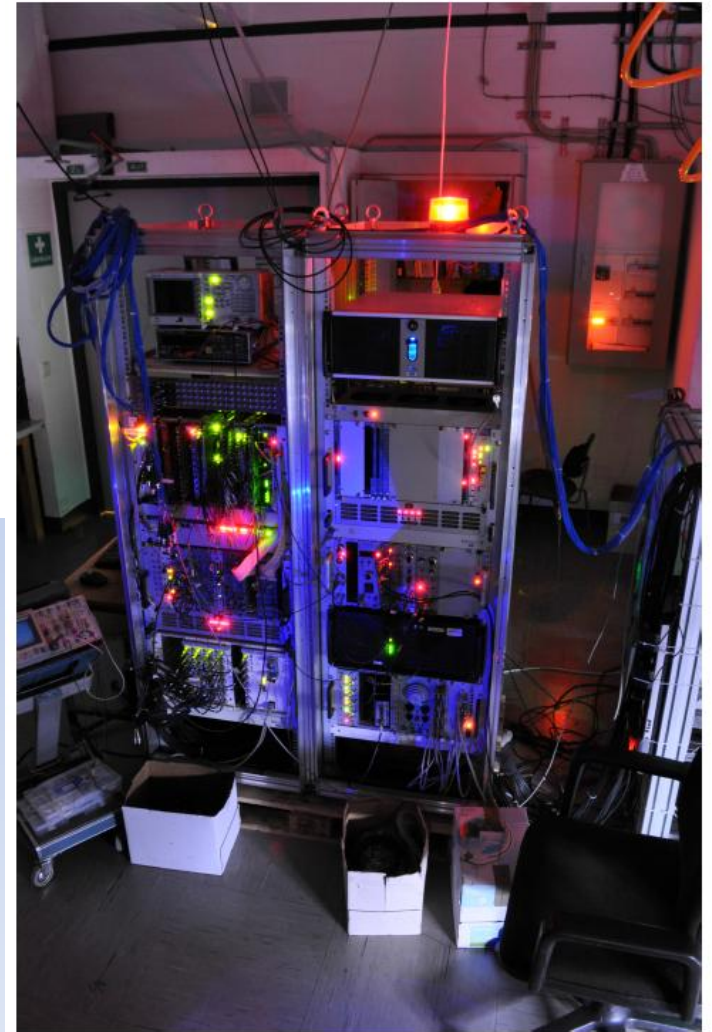
Tobias Triffterer

Experimentelle Hadronenphysik  
**Ruhr-Universität Bochum**

EMC workshop  
24<sup>th</sup> + 25<sup>th</sup> November 2014

RUHR  
UNIVERSITÄT  
BOCHUM

**RUB**



# Stimulated recovery

T. Kuske

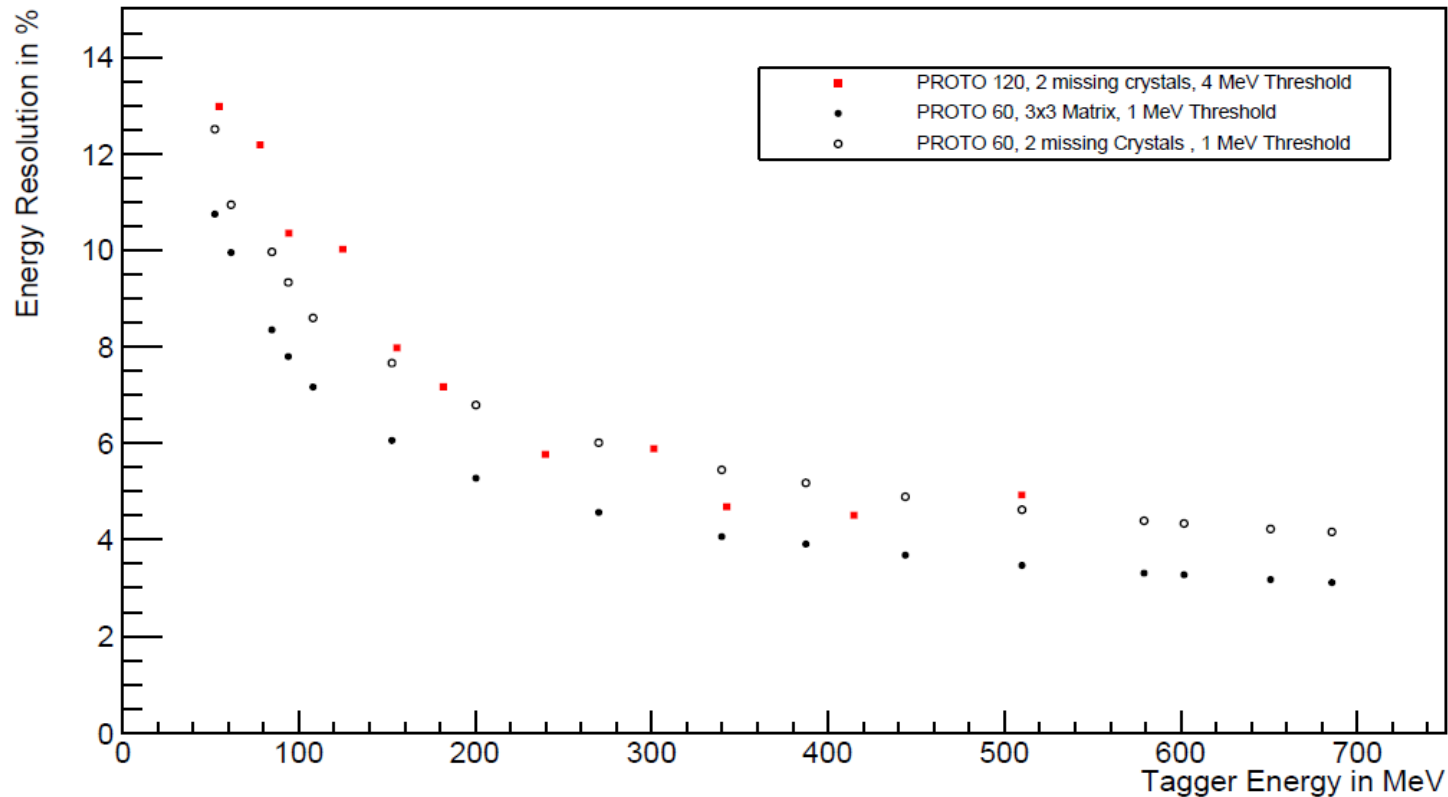


- $T = -25^{\circ}\text{C}$
- no ice formation
- VPT readout
- light pulser



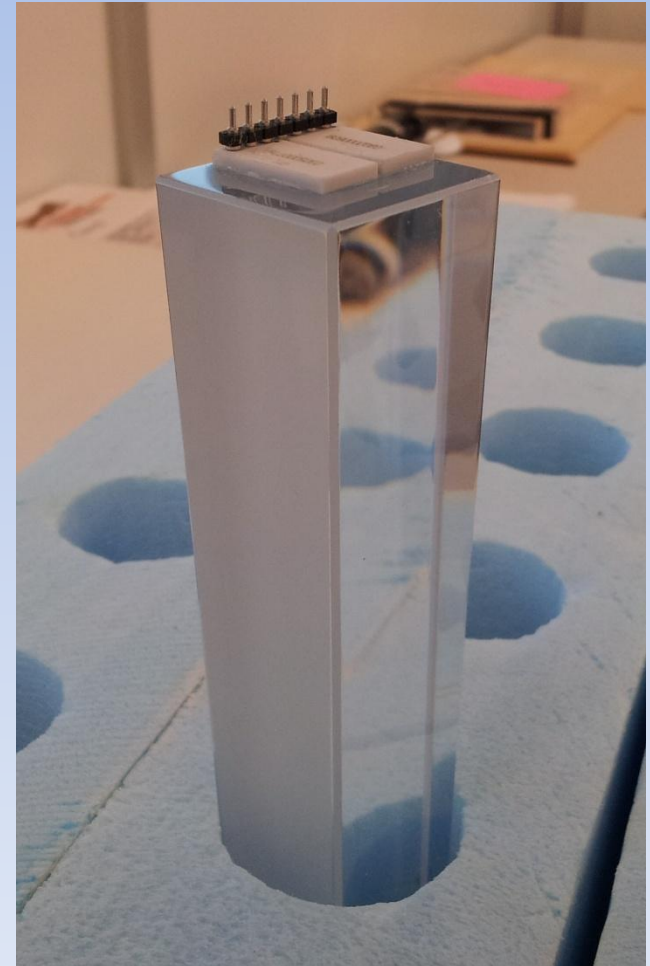
# Combined energy resolution

- 1 Crystal with highest energy  $\rightarrow$  central crystal
- 2 Threshold for central crystal
- 3 LG-information for central crystal and HG-information for peripheral crystals

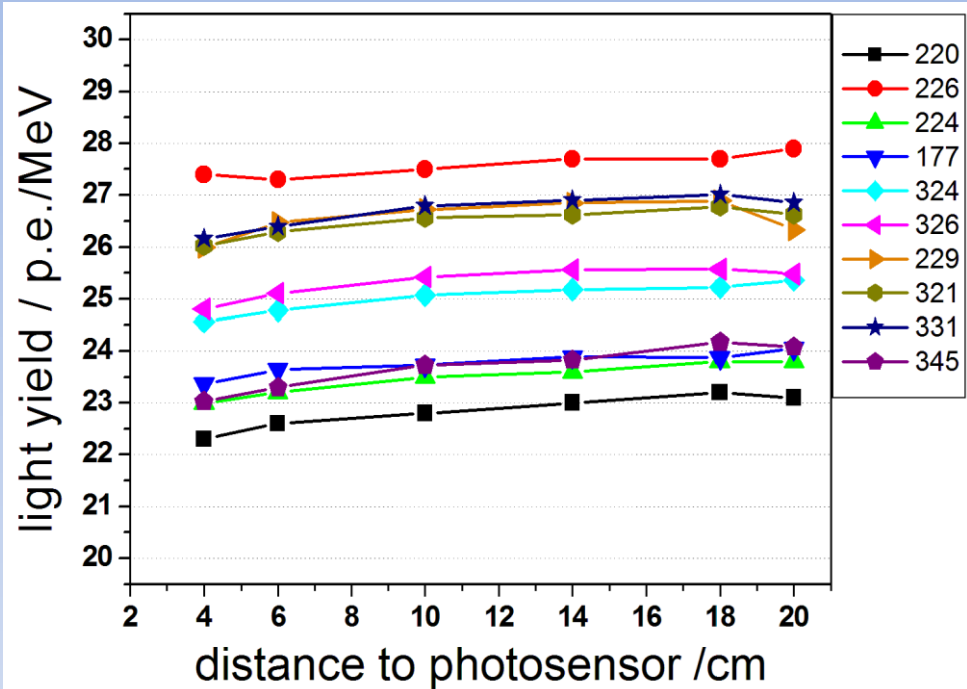
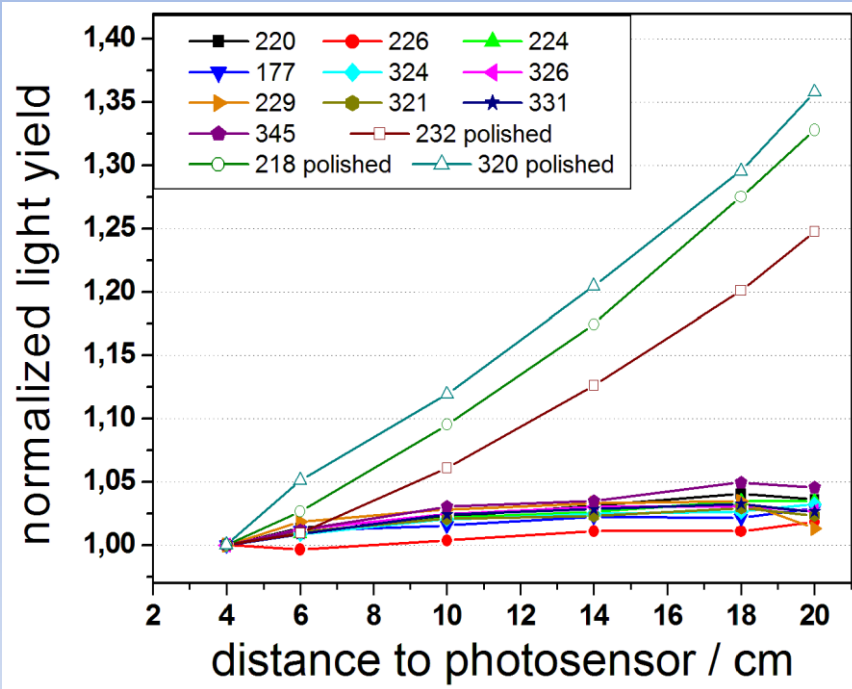


## Implementation of 9 depolished crystals in PROTO 120 (3x3 matrix)

- 9 type 2 crystals depolished at CERN with the setup used for CMS
- One lateral side depolished with  $R_a = 0.3 \mu\text{m}$  (value calculated from CMS data)
- All other sides still polished
- NUF has been measured for all depolished crystals



# NUF and LY of the depolished crystals



#	LY [p.e./MeV] polished	LY [p.e./MeV] depolished	change
220	29.0	23.1	20.3 %
226	31.7	27.9	12.0 %
224	27.9	23.8	14.7 %

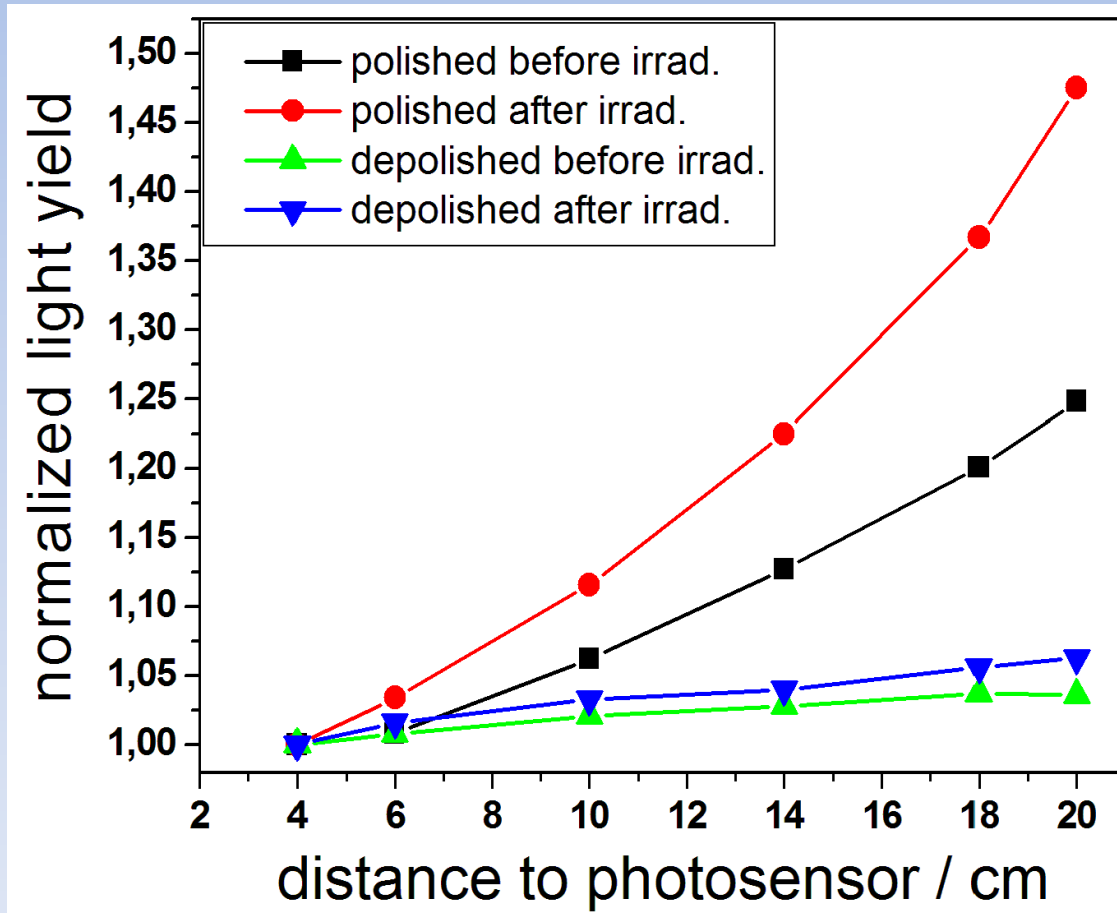
$^{137}\text{Cs}$  source  
on top  
of crystal

measured by S. Nazarenko, V. Dormenev

$T = +18\text{ }^\circ\text{C}$ , time gate =  $1\ \mu\text{s}$

# NUF and LY of the depolished crystals

- Depolishing also decreases the influence of radiation damage (30Gy  $\gamma$ ) on NUF



measured by  
S. Nazarenko, V. Dormenev

# A. Wilms: Status on APD-screening

delivery rate by Hamamatsu: 350 /week  
quality check: parameter limits @ 20°C

S11048 2014.11.14 Test Data  
No.0814008257-No.0819008647

Type No.	Serial No.	Position	VB(V)	M=100 VR(V)	M=100 ID(A)
S11048	0814008257	D05	418	389,7	4,30E-09
S11048	0814008258	H06	421	392,6	3,60E-09
S11048	0814008259	C04	420	391,0	4,90E-09
S11048	0814008260	E02	422	392,7	3,10E-09
S11048	0814008261	B03	417	389,4	3,40E-09
S11048	0814008263	D15	418	392,5	1,58E-08
S11048	0814008264	C08	418	389,9	3,00E-09
S11048	0814008265	B09	422	393,9	3,30E-09
S11048	0814008266	C10	421	392,9	3,40E-09
S11048	0814008267	F14	425	396,7	5,20E-09

**required for final application: HV for gain 150-200 @ -25°C**

set of measurements at  $\leq 5$  temperatures before **and** after irradiation ( $^{60}\text{Co}$  @ GI)

comparison: DC **and/or** pulsed light source ???

selected parameters: QE, C, ...

**request for a detailed quantitative status of the present capabilities.**